INA21x Voltage Output, Low- or High-Side Measurement, Bidirectional, Zero-Drift Series, Current-Shunt Monitors

1 Features

- Updated format to match new TI layout and flow. Tables, figures and cross-references use a new numbering sequence throughout the document.

  Wide Common-Mode Range: –0.3 V to 26 V
- Offset Voltage: ±35 µV (Maximum, INA210) (Enables Shunt Drops of 10-mV Full-Scale)
- Accuracy:
  - Gain Error (Maximum Over Temperature):
    - ±0.5% (Version C)
    - ±1% (Versions A and B)
  - 0.5-µV/°C Offset Drift (Maximum)
  - 10-ppm/°C Gain Drift (Maximum)
- Choice of Gains:
  - INA210: 200 V/V
  - INA211: 500 V/V
  - INA212: 1000 V/V
  - INA213: 50 V/V
  - INA214: 100 V/V
  - INA215: 75 V/V
- Quiescent Current: 100 µA (Maximum)
- SC70 and Thin UQFN Packages: All Models

2 Applications

- Notebook Computers
- Cell Phones
- Telecom Equipment
- Power Management
- Battery Chargers

3 Description

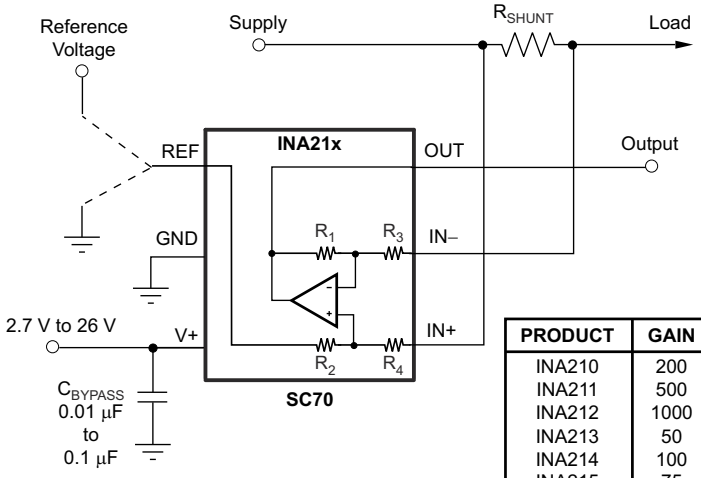
The INA21x are voltage-output, current-shunt monitors (also called current-sense amplifiers) that are commonly used for overcurrent protection, precision-current measurement for system optimization, or in closed-loop feedback circuits. This series of devices can sense drops across shunts at common-mode voltages from –0.3 V to 26 V, independent of the supply voltage. Six fixed gains are available: 50 V/V, 75 V/V, 100 V/V, 200 V/V, 500 V/V, or 1000 V/V. The low offset of the zero-drift architecture enables current sensing with maximum drops across the shunt as low as 10-mV full-scale.

These devices operate from a single 2.7-V to 26-V power supply, drawing a maximum of 100 µA of supply current. All versions are specified over the extended operating temperature range (–40°C to +125°C), and offered in SC70 and UQFN packages.

Device Information

PART NUMBER	PACKAGE(1)	BODY SIZE (NOM)
INA21x	SC70 (6)	2.00 mm × 1.25 mm
	UQFN (10)	1.80 mm × 1.40 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



PRODUCT	GAIN	R_3 and R_4	R_1 and R_2
INA210	200	5 kΩ	1 MΩ
INA211	500	2 kΩ	1 MΩ
INA212	1000	1 kΩ	1 MΩ
INA213	50	20 kΩ	1 MΩ
INA214	100	10 kΩ	1 MΩ
INA215	75	13.3 kΩ	1 MΩ

$V_{OUT} = (I_{LOAD} \times R_{SHUNT})$ Gain + V_{REF}

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Simplified Schematic

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4 Pin Configurations and Functions

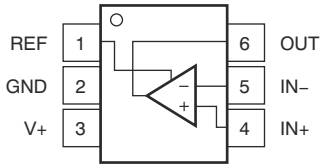
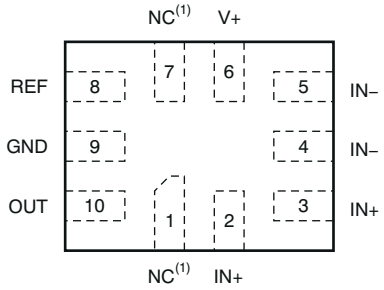


Figure 4-1. DCK Package 6-Pin SC70 Top View



A. NC(1) denotes no internal connection. These pins can be left floating or connected to any voltage between V– and V+.

Figure 4-2. RSW Package 10-Pin Thin UQFN Top View

Table 4-1. Pin Functions

PIN			I/O	DESCRIPTION
NAME	DCK	RSW		
GND	2	9	Analog	Ground
IN–	5	4, 5	Analog input	Connect to load side of shunt resistor
IN+	4	2, 3	Analog input	Connect to supply side of shunt resistor
NC	—	1, 7	—	Not internally connected. Leave floating or connect to ground.
OUT	6	10	Analog output	Output voltage
REF	1	8	Analog input	Reference voltage, 0 V to V+
V+	3	6	Analog	Power supply, 2.7 V to 26 V

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5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Supply voltage, V_S			26	V
Analog inputs, V_{IN+}, $V_{IN–}$ (2)	Differential (V_{IN+}) – ($V_{IN–}$)	–26	26	V
	Common-mode (Version A)(3)	GND – 0.3	26	V
	Common-mode (Version B)(3)	GND – 0.1	26	V
	Common-mode (Version C)(3)	GND – 0.1	26	V
REF input		GND – 0.3	(V_S) + 0.3	V
Output(3)		GND – 0.3	(V_S) + 0.3	V
Input current into any terminal(3)			5	mA
Operating temperature		–55	150	°C
Junction temperature			150	°C
Storage temperature, T_{stg}		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) V_{IN+} and $V_{IN–}$ are the voltages at the IN+ and IN– pins, respectively.
(3) Input voltage at any terminal may exceed the voltage shown if the current at that pin is limited to 5 mA.

5.2 ESD Ratings

			VALUE	UNIT
INA21x, (VERSION A)				
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±1000	
INA21x, (VERSIONS B AND C)				
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±3500	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{CM}	Common-mode input voltage		12		V
V_S	Operating supply voltage		5		V
T_A	Operating free-air temperature	–40		125	°C

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5.4 Thermal Information

THERMAL METRIC[1]		INA21x		UNIT
		DCK (SC70)	RSW (UQFN)	
		6 PINS	10 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	227.3	107.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	79.5	56.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	72.1	18.7	°C/W
ψ_{JT}	Junction-to-top characterization parameter	3.6	1.1	°C/W
ψ_{JB}	Junction-to-board characterization parameter	70.4	18.7	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

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5.5 Electrical Characteristics

at T_A = 25°C, V_{SENSE} = V_{IN+} – $V_{IN–}$
INA210, INA213, INA214, and INA215: V_S = 5 V, V_{IN+} = 12 V, and V_{REF} = V_S / 2, unless otherwise noted
INA211 and INA212: V_S = 12 V, V_{IN+} = 12 V, and V_{REF} = V_S / 2, unless otherwise noted

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT							
V_{CM}	Common-mode input range		Version A T_A = –40°C to +125°C	–0.3		26	V
			Versions B and C T_A = –40°C to +125°C	–0.1		26	
CMRR	Common-mode rejection ratio	INA210, INA211, INA212, INA214, INA215	V_{IN+} = 0 V to 26 V V_{SENSE} = 0 mV T_A = –40°C to +125°C	105	140		dB
		INA213	V_{IN+} = 0 V to 26 V V_{SENSE} = 0 mV T_A = –40°C to +125°C	100	120		
V_O	Offset voltage, RTI[1]	INA210, INA211, INA212	V_{SENSE} = 0 mV		±0.55	±35	µV
		INA213	V_{SENSE} = 0 mV		±5	±100	
		INA214, INA215	V_{SENSE} = 0 mV		±1	±60	
dV_{OS}/dT	RTI vs temperature		V_{SENSE} = 0 mV T_A = –40°C to +125°C		0.1	0.5	µV/°C
PSRR	RTI vs power supply ratio		V_S = 2.7 V to 18 V V_{IN+} = 18 V V_{SENSE} = 0 mV		±0.1	±10	µV/V
I_{IB}	Input bias current		V_{SENSE} = 0 mV	15	28	35	µA
I_{IO}	Input offset current		V_{SENSE} = 0 mV		±0.02		µA
OUTPUT							
G	Gain	INA210			200		V/V
		INA211			500		
		INA212			1000		
		INA213			50		
		INA214			100		
		INA215			75		
E_G	Gain error		V_{SENSE} = –5 mV to 5 mV T_A = –40°C to +125°C (Versions A and B)		±0.02%	±1%	
			V_{SENSE} = –5 mV to 5 mV T_A = –40°C to +125°C (Version C)		±0.02%	±0.5%	
	Gain error vs temperature		T_A = –40°C to +125°C		3	10	ppm/°C
	Nonlinearity error		V_{SENSE} = –5 mV to 5 mV		±0.01%		
	Maximum capacitive load		No sustained oscillation		1		nF
VOLTAGE OUTPUT[2]							
	Swing to V+ power-supply rail		R_L = 10 kΩ to GND T_A = –40°C to +125°C		(V+) – 0.05	(V+) – 0.2	V
	Swing to GND		R_L = 10 kΩ to GND T_A = –40°C to +125°C		(V_{GND}) + 0.005	(V_{GND}) + 0.05	V
FREQUENCY RESPONSE							
BW	Bandwidth		C_{LOAD} = 10 pF, INA210		14		kHz
			C_{LOAD} = 10 pF, INA211		7		
			C_{LOAD} = 10 pF, INA212		4		
			C_{LOAD} = 10 pF, INA213		80		
			C_{LOAD} = 10 pF, INA214		30		
			C_{LOAD} = 10 pF, INA215		40		
SR	Slew rate				0.4		V/µs
NOISE, RTI[1]							

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5.5 Electrical Characteristics (continued)

at T_A = 25°C, $V_{SENSE} = V_{IN+} – V_{IN–}$
INA210, INA213, INA214, and INA215: V_S = 5 V, V_{IN+} = 12 V, and $V_{REF} = V_S / 2$, unless otherwise noted
INA211 and INA212: V_S = 12 V, V_{IN+} = 12 V, and $V_{REF} = V_S / 2$, unless otherwise noted

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Voltage noise density				25		nV/√Hz
POWER SUPPLY							
V_S	Operating voltage range		T_A = –40°C to +125°C	2.7		26	V
I_Q	Quiescent current		V_{SENSE} = 0 mV		65	100	µA
	I_Q over temperature		T_A = –40°C to +125°C			115	µA
TEMPERATURE RANGE							
	Specified range			–40		125	°C
	Operating range			–55		150	°C
θ_{JA}	Thermal resistance	SC70			250		°C/W
		Thin UQFN			80		°C/W

(1) RTI = referred-to-input.
(2) See Typical Characteristic curve, *Output Voltage Swing vs Output Current* (Figure 5-10).

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5.6 Typical Characteristics

The INA210 is used for typical characteristics at T_A = 25°C, V_S = 5 V, V_{IN+} = 12 V, and V_{REF} = V_S / 2, unless otherwise noted.

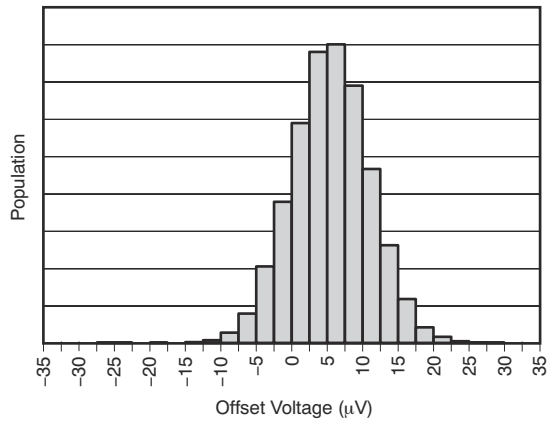


Figure 5-1. Input Offset Voltage Production Distribution

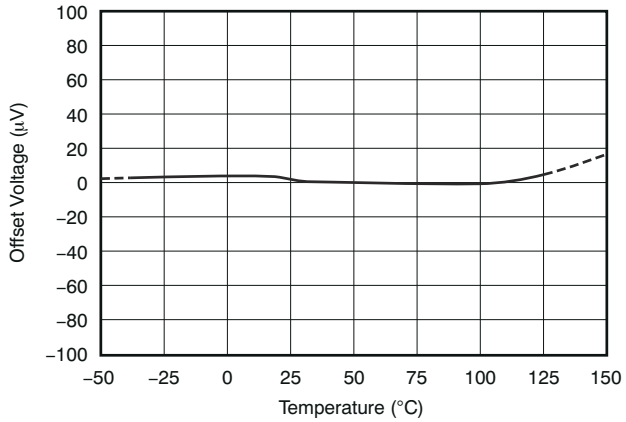


Figure 5-2. Offset Voltage vs Temperature

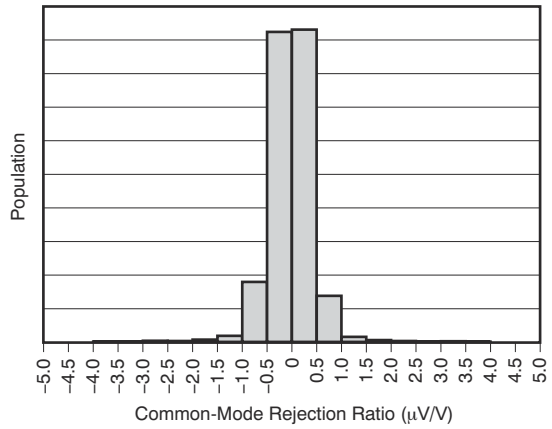


Figure 5-3. Common-Mode Rejection Production Distribution

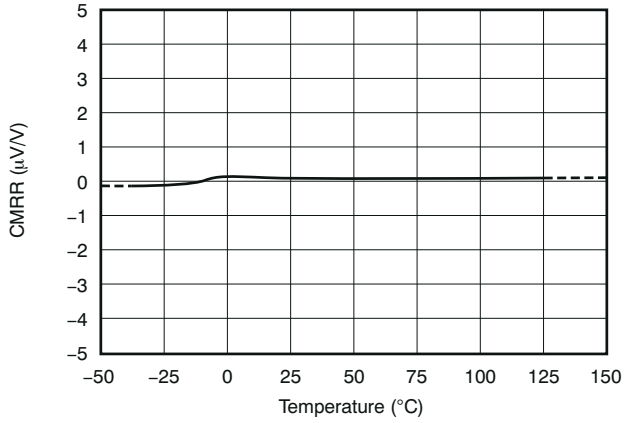


Figure 5-4. Common-Mode Rejection Ratio vs Temperature

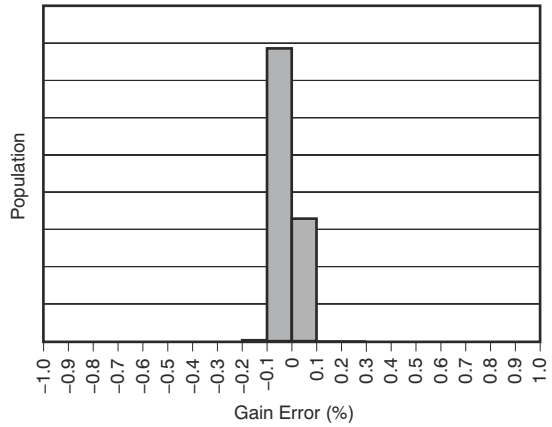


Figure 5-5. Gain Error Production Distribution

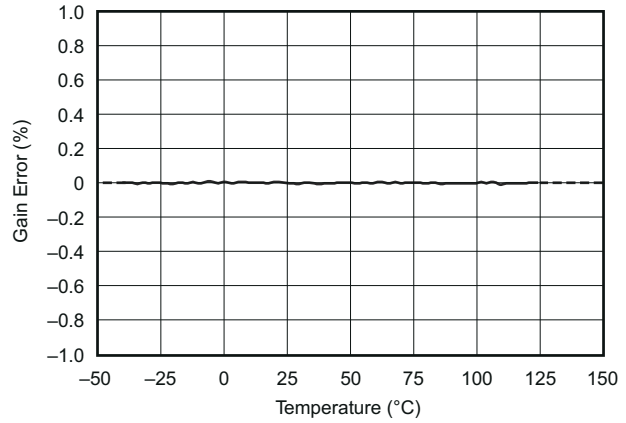


Figure 5-6. Gain Error vs Temperature

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5.6 Typical Characteristics (continued)

The INA210 is used for typical characteristics at T_A = 25°C, V_S = 5 V, V_{IN+} = 12 V, and V_{REF} = V_S / 2, unless otherwise noted.

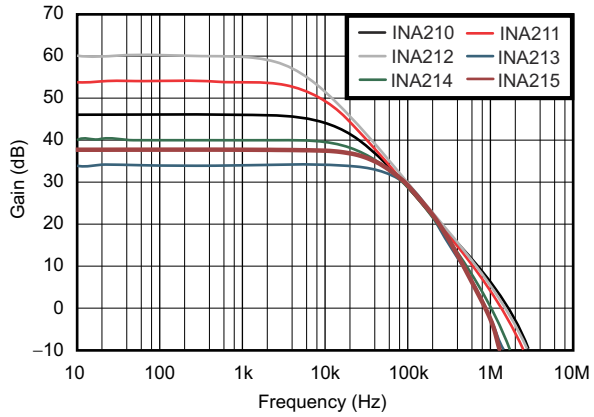
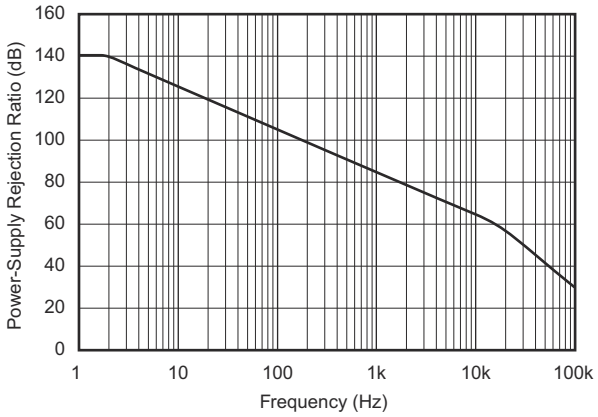


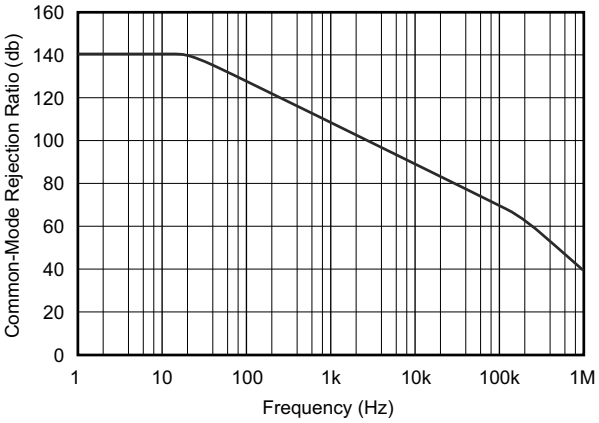
Figure 5-7. Gain vs Frequency



V_S = 5 V + 250-mV sine disturbance

V_{CM} = 0 V V_{REF} = 2.5 V V_{DIF} = shorted

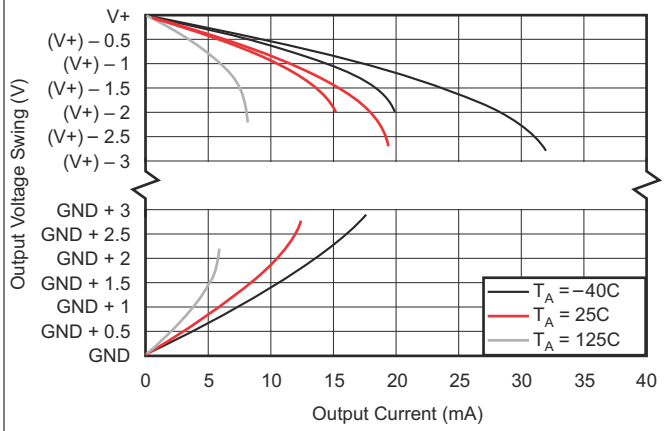
Figure 5-8. Power-Supply Rejection Ratio vs Frequency



V_S = 5 V V_{CM} = 1 V sine V_{DIF} = shorted

V_{REF} = 2.5 V

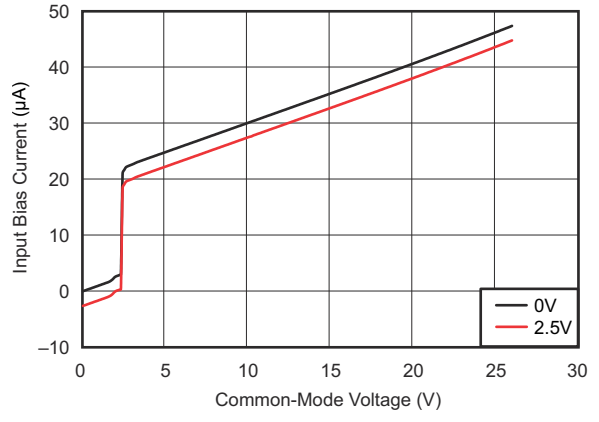
Figure 5-9. Common-Mode Rejection Ratio vs Frequency



V_S = 2.7 V V_S = 2.7 V V_S = 5 V to 26 V

V_S = 2.7 V to 26 V

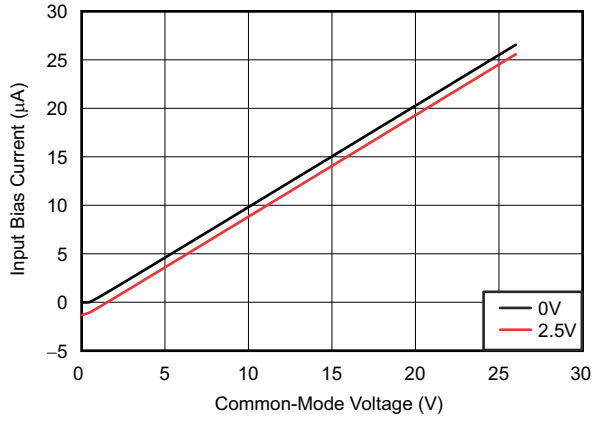
Figure 5-10. Output Voltage Swing vs Output Current



I_{B+}, $I_{B–}$, V_{REF} = 0 V

I_{B+}, $I_{B–}$, V_{REF} = 2.5 V

Figure 5-11. Input Bias Current vs Common-Mode Voltage With Supply Voltage = 5 V



I_{B+}, $I_{B–}$, V_{REF} = 0 V I_{B+}, $I_{B–}$, V_{REF} = 2.5 V I_{B+}, V_{REF} = 2.5 V

Figure 5-12. Input Bias Current vs Common-Mode Voltage With Supply Voltage = 0 V (Shutdown)

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5.6 Typical Characteristics (continued)

The INA210 is used for typical characteristics at T_A = 25°C, V_S = 5 V, V_{IN+} = 12 V, and V_{REF} = V_S / 2, unless otherwise noted.

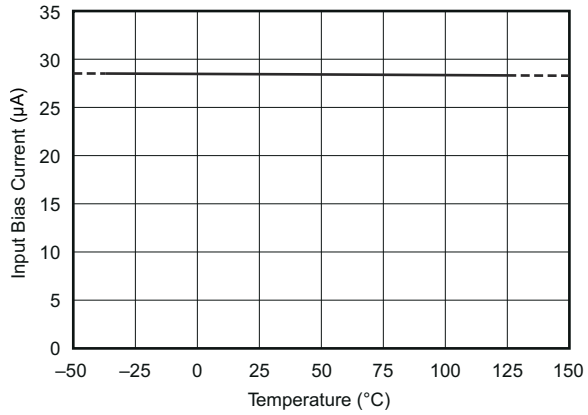


Figure 5-13. Input Bias Current vs Temperature

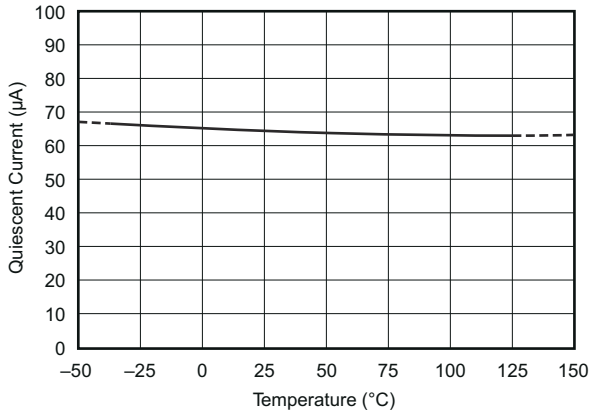
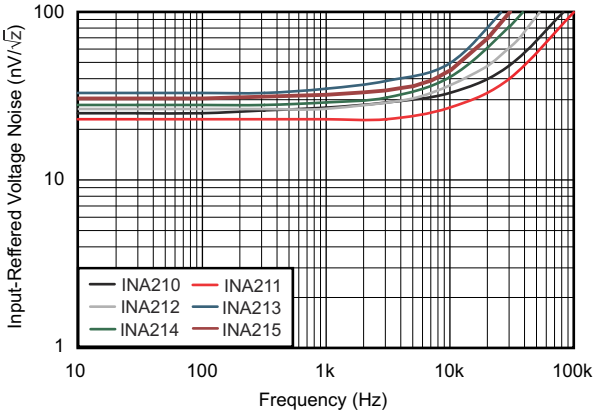
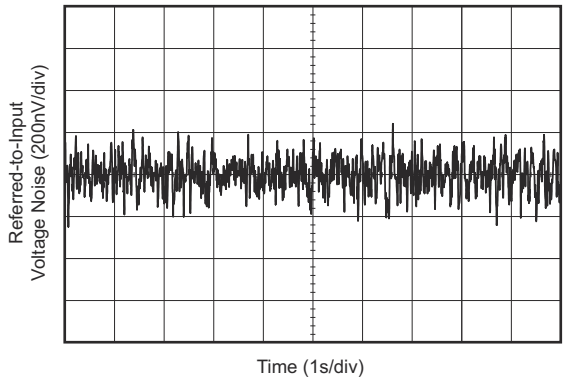


Figure 5-14. Quiescent Current vs Temperature



V_S = 2.5 V V_{REF} = 0 V $V_{IN–}$, V_{IN+} = 0 V

Figure 5-15. Input-Referred Voltage Noise vs Frequency



V_S = 2.5 V V_{CM} = 0 V V_{DIF} = 0 V
V_{REF} = 0 V

Figure 5-16. 0.1-Hz to 10-Hz Voltage Noise (Referred-To-Input)

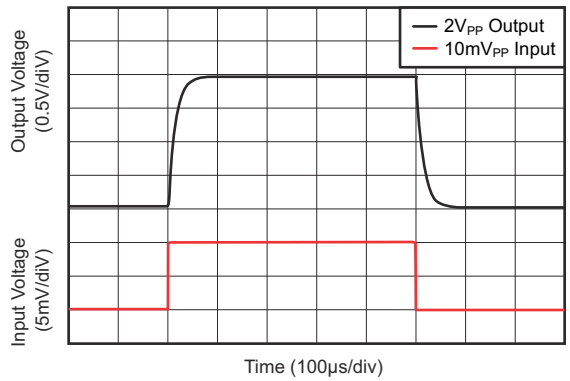


Figure 5-17. Step Response (10-mV_{PP} Input Step)

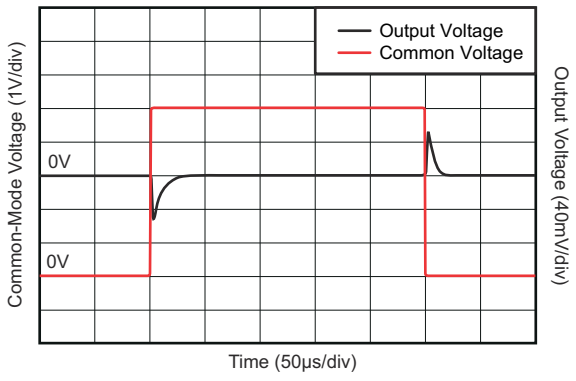
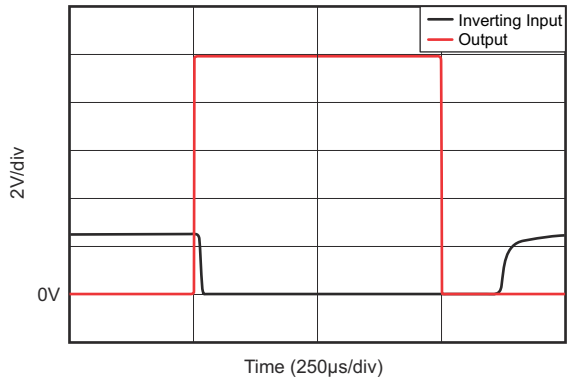


Figure 5-18. Common-Mode Voltage Transient Response

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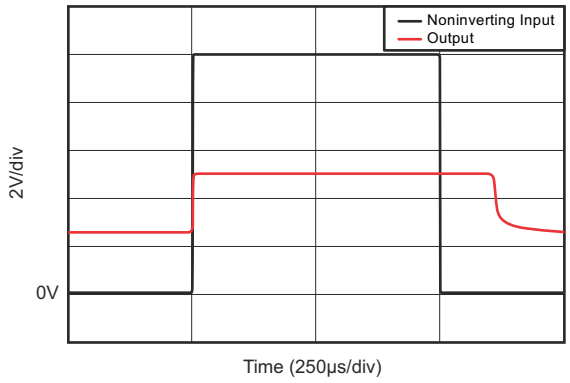
5.6 Typical Characteristics (continued)

The INA210 is used for typical characteristics at T_A = 25°C, V_S = 5 V, V_{IN+} = 12 V, and V_{REF} = V_S / 2, unless otherwise noted.



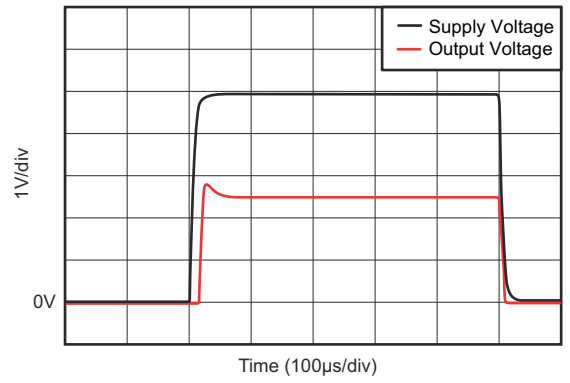
V_S = 5 V V_{CM} = 12 V V_{REF} = 2.5 V

Figure 5-19. Inverting Differential Input Overload



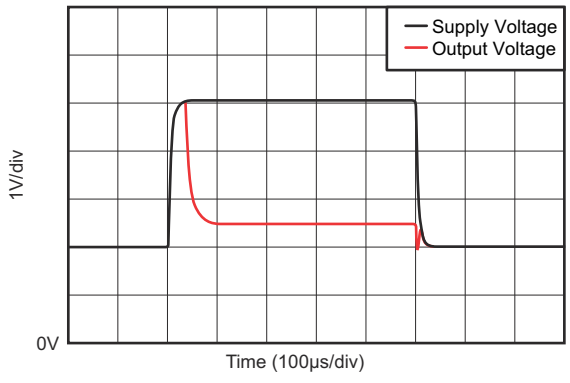
V_S = 5 V V_{CM} = 12 V V_{REF} = 2.5 V

Figure 5-20. Noninverting Differential Input Overload



V_S = 5 V 1-kHz step with V_{DIFF} = 0 V V_{REF} = 2.5 V

Figure 5-21. Start-Up Response



V_S = 5 V 1-kHz step with V_{DIFF} = 0 V V_{REF} = 2.5 V

Figure 5-22. Brownout Recovery

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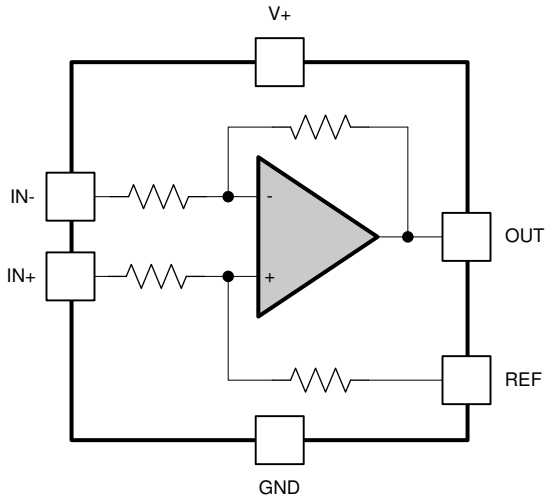
6 Detailed Description

6.1 Overview

The INA21x are 26-V, common-mode, zero-drift topology, current-sensing amplifiers that can be used in both low-side and high-side configurations. These specially-designed, current-sensing amplifiers are able to accurately measure voltages developed across current-sensing resistors on common-mode voltages that far exceed the supply voltage powering the device. Current can be measured on input voltage rails as high as 26 V while the device can be powered from supply voltages as low as 2.7 V.

The zero-drift topology enables high-precision measurements with maximum input offset voltages as low as 35 µV with a maximum temperature contribution of 0.5 µV/°C over the full temperature range of –40°C to +125°C.

6.2 Functional Block Diagram



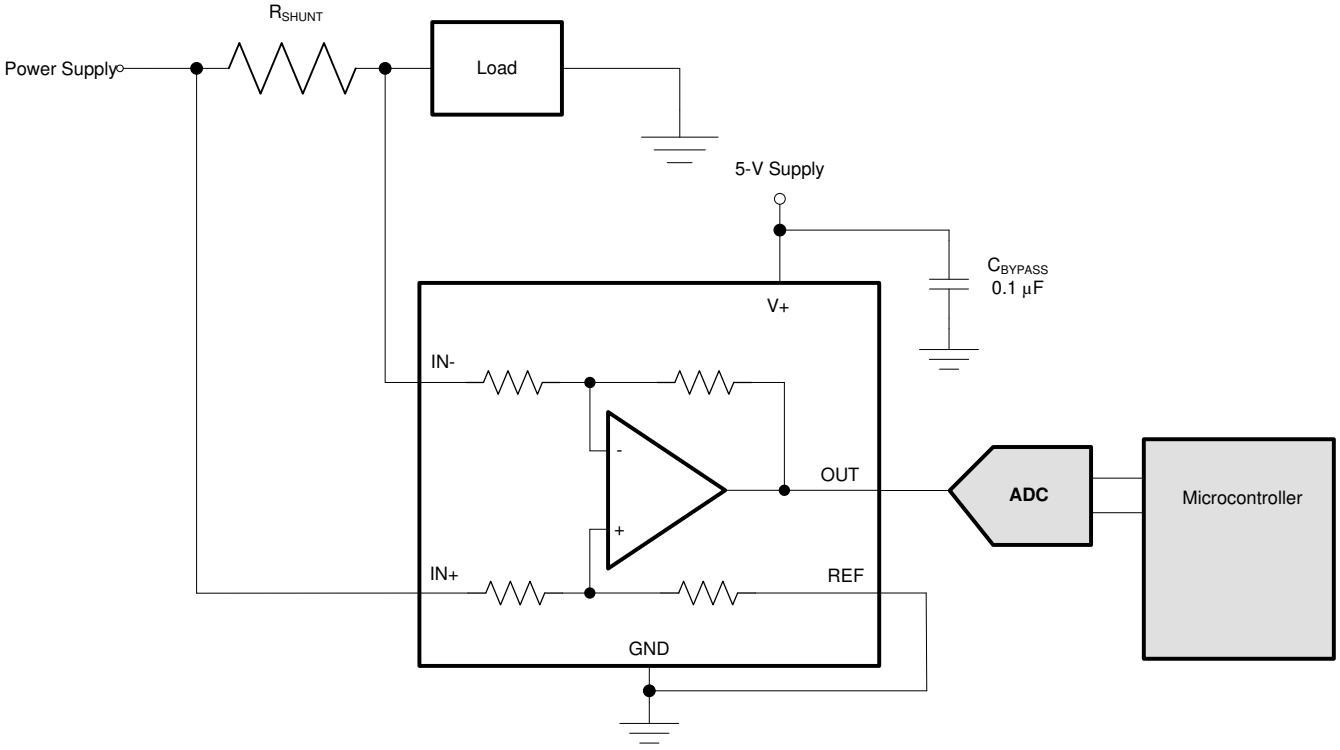
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6.3 Feature Description

6.3.1 Basic Connections

Figure 6-1 shows the basic connections of the INA21x. Connect the input pins (IN+ and IN–) as closely as possible to the shunt resistor to minimize any resistance in series with the shunt resistor.



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Figure 6-1. Typical Application

Power-supply bypass capacitors are required for stability. Applications with noisy or high-impedance power supplies may require additional decoupling capacitors to reject power-supply noise. Connect bypass capacitors close to the device pins.

On the RSW package options, two pins are provided for each input. Tie these pins together (that is, tie IN+ to IN+ and tie IN– to IN–).

6.3.2 Selecting R_S

The zero-drift offset performance of the INA21x offers several benefits. Most often, the primary advantage of the low offset characteristic enables lower full-scale drops across the shunt. For example, non-zero-drift current shunt monitors typically require a full-scale range of 100 mV.

The INA21x series gives equivalent accuracy at a full-scale range on the order of 10 mV. This accuracy reduces shunt dissipation by an order of magnitude with many additional benefits.

Alternatively, there are applications that must measure current over a wide dynamic range that can take advantage of the low offset on the low end of the measurement. Most often, these applications can use the lower gains of the INA213, INA214, or INA215 to accommodate larger shunt drops on the upper end of the scale. For instance, an INA213 operating on a 3.3-V supply can easily handle a full-scale shunt drop of 60 mV, with only 100 µV of offset.

6.4 Device Functional Modes

6.4.1 Input Filtering

An obvious and straightforward filtering location is at the device output. However, this location negates the advantage of the low output impedance of the internal buffer. The only other filtering option is at the device input pins. This location, though, does require consideration of the ±30% tolerance of the internal resistances. Figure 6-2 shows a filter placed at the inputs pins.

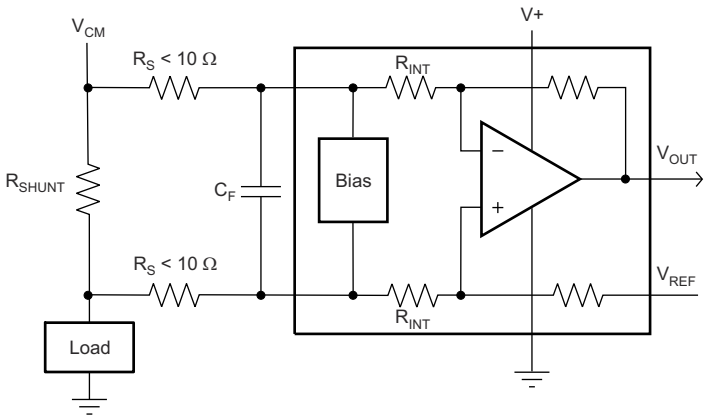


Figure 6-2. Filter at Input Pins

The addition of external series resistance, however, creates an additional error in the measurement so the value of these series resistors must be kept to 10 Ω (or less, if possible) to reduce impact to accuracy. The internal bias network shown in Figure 6-2 present at the input pins creates a mismatch in input bias currents when a differential voltage is applied between the input pins. If additional external series filter resistors are added to the circuit, the mismatch in bias currents results in a mismatch of voltage drops across the filter resistors. This mismatch creates a differential error voltage that subtracts from the voltage developed at the shunt resistor. This error results in a voltage at the device input pins that is different than the voltage developed across the shunt resistor. Without the additional series resistance, the mismatch in input bias currents has little effect on device operation. The amount of error these external filter resistors add to the measurement can be calculated using Equation 2 where the gain error factor is calculated using Equation 1.

The amount of variance in the differential voltage present at the device input relative to the voltage developed at the shunt resistor is based both on the external series resistance value as well as the internal input resistors, R3 and R4 (or R_{INT} as shown in Figure 6-2). The reduction of the shunt voltage reaching the device input pins appears as a gain error when comparing the output voltage relative to the voltage across the shunt resistor. A factor can be calculated to determine the amount of gain error that is introduced by the addition of external series resistance. The equation used to calculate the expected deviation from the shunt voltage to what is measured at the device input pins is given in Equation 1:

$$\text{Gain Error Factor} = \frac{(1250 \times R_{INT})}{(1250 \times R_S) + (1250 \times R_{INT}) + (R_S \times R_{INT})} \quad (1)$$

where:

- R_{INT} is the internal input resistor (R3 and R4), and
- R_S is the external series resistance.

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With the adjustment factor from Equation 1, including the device internal input resistance, this factor varies with each gain version, as shown in Table 6-1. Each individual device gain error factor is shown in Table 6-2.

Table 6-1. Input Resistance

PRODUCT	GAIN	R_{INT} (kΩ)
INA210	200	5
INA211	500	2
INA212	1000	1
INA213	50	20
INA214	100	10
INA215	75	13.3

Table 6-2. Device Gain Error Factor

PRODUCT	SIMPLIFIED GAIN ERROR FACTOR
INA210	$\frac{1000}{R_S + 1000}$
INA211	$\frac{10{,}000}{(13 \times R_S) + 10{,}000}$
INA212	$\frac{5000}{(9 \times R_S) + 5000}$
INA213	$\frac{20{,}000}{(17 \times R_S) + 20{,}000}$
INA214	$\frac{10{,}000}{(9 \times R_S) + 10{,}000}$
INA215	$\frac{8{,}000}{(7 \times R_S) + 8{,}000}$

The gain error that can be expected from the addition of the external series resistors can then be calculated based on Equation 2:

$$\text{Gain Error (\%)} = 100 - (100 \times \text{Gain Error Factor}) \quad (2)$$

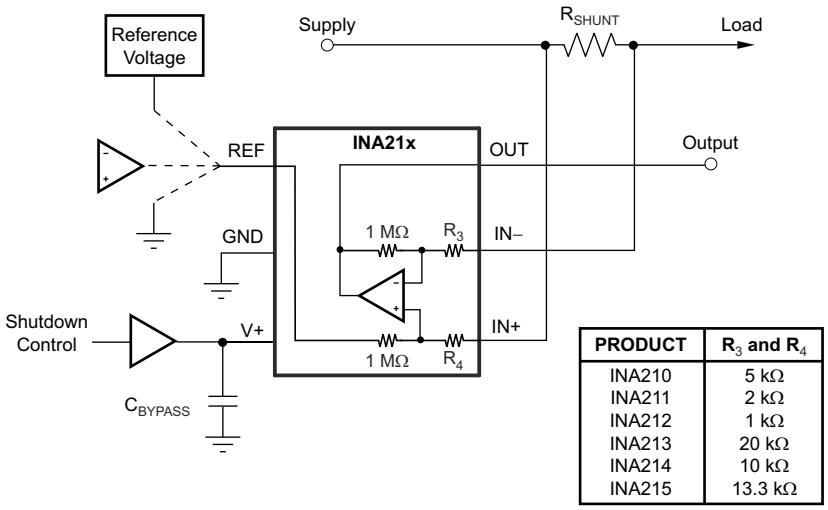
For example, using an INA212 and the corresponding gain error equation from Table 6-2, a series resistance of 10 Ω results in a gain error factor of 0.982. The corresponding gain error is then calculated using Equation 2, resulting in a gain error of approximately 1.77% solely because of the external 10-Ω series resistors. Using an INA213 with the same 10-Ω series resistor results in a gain error factor of 0.991 and a gain error of 0.84% again solely because of these external resistors.

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6.4.2 Shutting Down the INA21x Series

Although the INA21x series does not have a shutdown pin, the low power consumption of the device allows the output of a logic gate or transistor switch to power the INA21x. This gate or switch turns on and turns off the INA21x power-supply quiescent current.

However, in current shunt monitoring applications, there is also a concern for how much current is drained from the shunt circuit in shutdown conditions. Evaluating this current drain involves considering the simplified schematic of the INA21x in shutdown mode, as shown in Figure 6-3.



PRODUCT	R_3 and R_4
INA210	5 kΩ
INA211	2 kΩ
INA212	1 kΩ
INA213	20 kΩ
INA214	10 kΩ
INA215	13.3 kΩ

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1-MΩ paths from shunt inputs to reference and INA21x outputs.

Figure 6-3. Basic Circuit for Shutting Down The INA21x With a Grounded Reference

Note that there is typically slightly more than 1-MΩ impedance (from the combination of 1-MΩ feedback and 5-kΩ input resistors) from each input of the INA21x to the OUT pin and to the REF pin. The amount of current flowing through these pins depends on the respective ultimate connection. For example, if the REF pin is grounded, the calculation of the effect of the 1-MΩ impedance from the shunt to ground is straightforward. However, if the reference or op amp is powered while the INA21x is shut down, the calculation is direct; instead of assuming 1 MΩ to ground, however, assume 1 MΩ to the reference voltage. If the reference or op amp is also shut down, some knowledge of the reference or op amp output impedance under shutdown conditions is required. For instance, if the reference source behaves as an open circuit when not powered, little or no current flows through the 1-MΩ path.

Regarding the 1-MΩ path to the output pin, the output stage of a disabled INA21x does constitute a good path to ground. Consequently, this current is directly proportional to a shunt common-mode voltage present across a 1-MΩ resistor.

As a final note, when the device is powered up, there is an additional, nearly constant, and well-matched 25 µA that flows in each of the inputs as long as the shunt common-mode voltage is 3 V or higher. Below 2-V common-mode, the only current effects are the result of the 1-MΩ resistors.

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6.4.3 REF Input Impedance Effects

As with any difference amplifier, the INA21x series common-mode rejection ratio is affected by any impedance present at the REF input. This concern is not a problem when the REF pin is connected directly to most references or power supplies. When using resistive dividers from the power supply or a reference voltage, the REF pin must be buffered by an op amp.

In systems where the INA21x output can be sensed differentially, such as by a differential input analog-to-digital converter (ADC) or by using two separate ADC inputs, the effects of external impedance on the REF input can be cancelled. Figure 6-4 depicts a method of taking the output from the INA21x by using the REF pin as a reference.

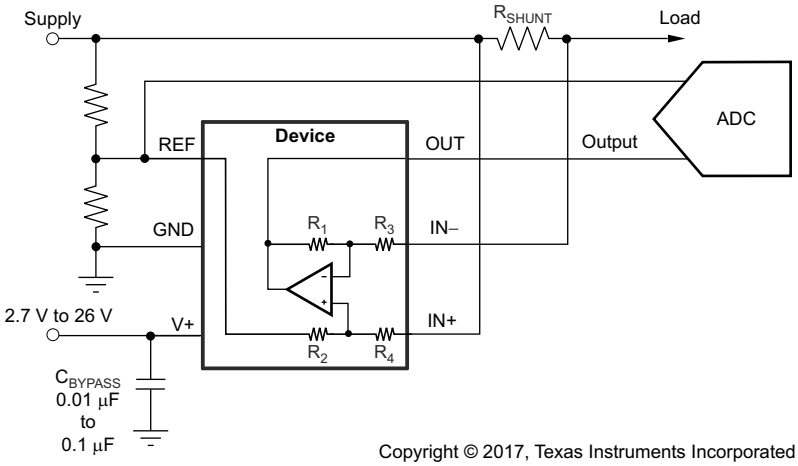


Figure 6-4. Sensing the INA21x to Cancel the Effects of Impedance on the REF Input

6.4.4 Using The INA21x With Common-Mode Transients Above 26 V

With a small amount of additional circuitry, the INA21x series can be used in circuits subject to transients higher than 26 V, such as automotive applications. Use only zener diode or zener-type transient absorbers (sometimes referred to as *transzorbs*) ;any other type of transient absorber has an unacceptable time delay. Start by adding a pair of resistors as a working impedance for the zener; see Figure 6-5. Keeping these resistors as small as possible is preferable, typically around 10 Ω. Larger values can be used with an effect on gain that is discussed in the *Section 6.4.1* section. Because this circuit limits only short-term transients, many applications are satisfied with a 10-Ω resistor along with conventional zener diodes of the lowest power rating that can be found. This combination uses the least amount of board space. These diodes can be found in packages as small as SOT-523 or SOD-523.

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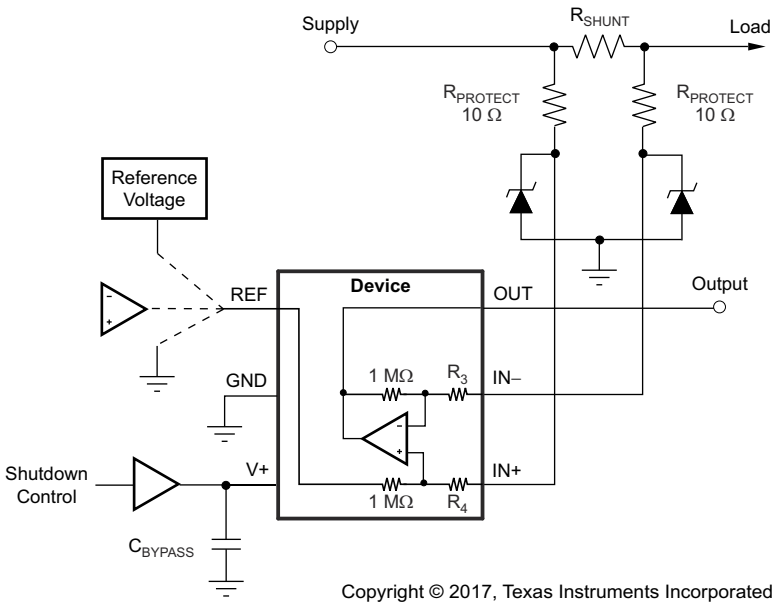


Figure 6-5. INA21x Transient Protection Using Dual Zener Diodes

In the event that low-power zeners do not have sufficient transient absorption capability and a higher power transzorb must be used, the most package-efficient solution then involves using a single transzorb and back-to-back diodes between the device inputs. The most space-efficient solutions are dual series-connected diodes in a single SOT-523 or SOD-523 package. This method is shown in Figure 6-6. In either of these examples, the total board area required by the INA21x with all protective components is less than that of an SO-8 package, and only slightly greater than that of an MSOP-8 package.

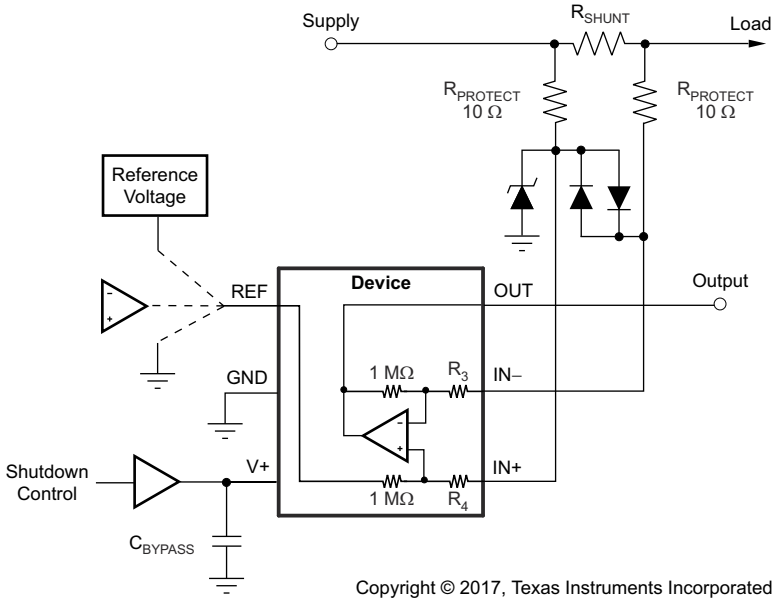
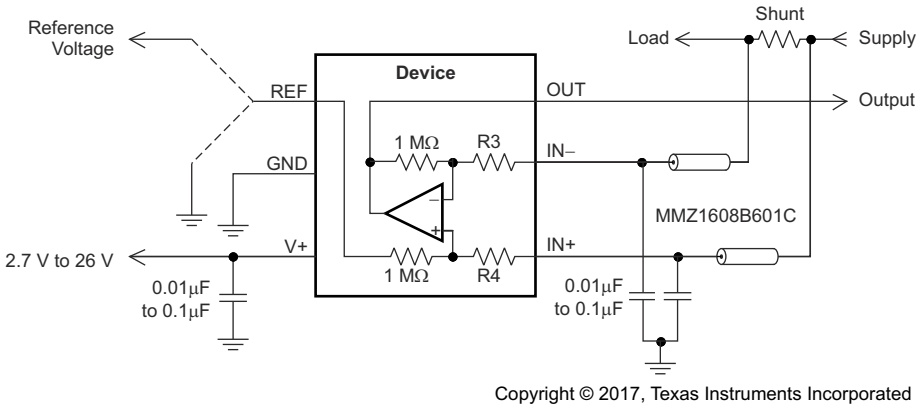


Figure 6-6. INA21x Transient Protection Using a Single Transzorb and Input Clamps

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6.4.5 Improving Transient Robustness

Applications involving large input transients with excessive dV/dt above 2 kV per microsecond present at the device input pins may cause damage to the internal ESD structures on version A devices. This potential damage is a result of the internal latching of the ESD structure to ground when this transient occurs at the input. With significant current available in most current-sensing applications, the large current flowing through the input transient-triggered, ground-shorted ESD structure quickly results in damage to the silicon. External filtering can be used to attenuate the transient signal prior to reaching the inputs to avoid the latching condition. Care must be taken to ensure that external series input resistance does not significantly impact gain error accuracy. For accuracy purposes, keep these resistances under 10 Ω if possible. Ferrite beads are recommended for this filter because of their inherently low dc ohmic value. Ferrite beads with less than 10 Ω of resistance at dc and over 600 Ω of resistance at 100 MHz to 200 MHz are recommended. The recommended capacitor values for this filter are between 0.01 µF and 0.1 µF to ensure adequate attenuation in the high-frequency region. This protection scheme is shown in Figure 6-7.



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Figure 6-7. Transient Protection

To minimize the cost of adding these external components to protect the device in applications where large transient signals may be present, version B and C devices are now available with new ESD structures that are not susceptible to this latching condition. Version B and C devices are incapable of sustaining these damage-causing latched conditions so these devices do not have the same sensitivity to the transients that the version A devices have, thus making the version B and C devices a better fit for these applications.

7 Application and Implementation

Note

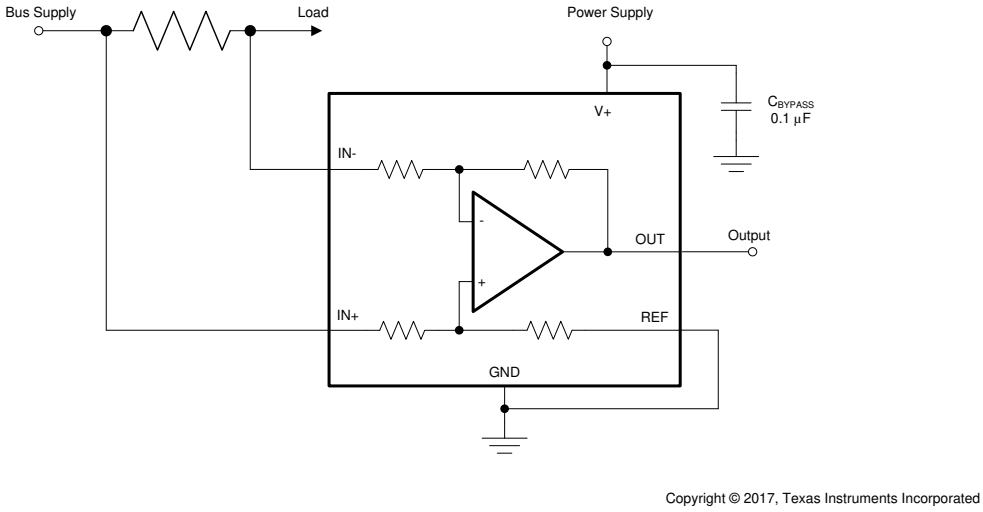
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

7.1 Application Information

The INA21x devices measure the voltage developed across a current-sensing resistor when current passes through the device. The ability to drive the reference pin to adjust the functionality of the output signal offers multiple configurations, as discussed throughout this section.

7.2 Typical Applications

7.2.1 Unidirectional Operation



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Figure 7-1. Unidirectional Application Schematic

7.2.1.1 Design Requirements

The device can be configured to monitor current flowing in one direction (unidirectional) or in both directions (bidirectional) depending on how the REF pin is configured. The most common case is unidirectional where the output is set to ground when no current is flowing by connecting the REF pin to ground, as shown in Figure 7-1. When the input signal increases, the output voltage at the OUT pin increases.

7.2.1.2 Detailed Design Procedure

The linear range of the output stage is limited in how close the output voltage can approach ground under zero input conditions. In unidirectional applications where measuring very low input currents is desirable, bias the REF pin to a convenient value above 50 mV to get the output into the linear range of the device. To limit common-mode rejection errors, TI recommends buffering the reference voltage connected to the REF pin.

A less frequently-used output biasing method is to connect the REF pin to the supply voltage, V+. This method results in the output voltage saturating at 200 mV below the supply voltage when no differential input signal is present. This method is similar to the output saturated low condition with no input signal when the REF pin is connected to ground. The output voltage in this configuration only responds to negative currents that develop negative differential input voltage relative to the device IN– pin. Under these conditions, when the differential input signal increases negatively, the output voltage moves downward from the saturated supply voltage. The voltage applied to the REF pin must not exceed the device supply voltage.

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7.2.1.3 Application Curve

An example output response of a unidirectional configuration is shown in Figure 7-2. With the REF pin connected directly to ground, the output voltage is biased to this zero output level. The output rises above the reference voltage for positive differential input signals but cannot fall below the reference voltage for negative differential input signals because of the grounded reference voltage.

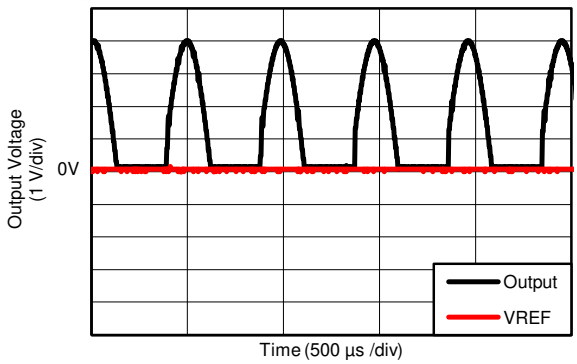
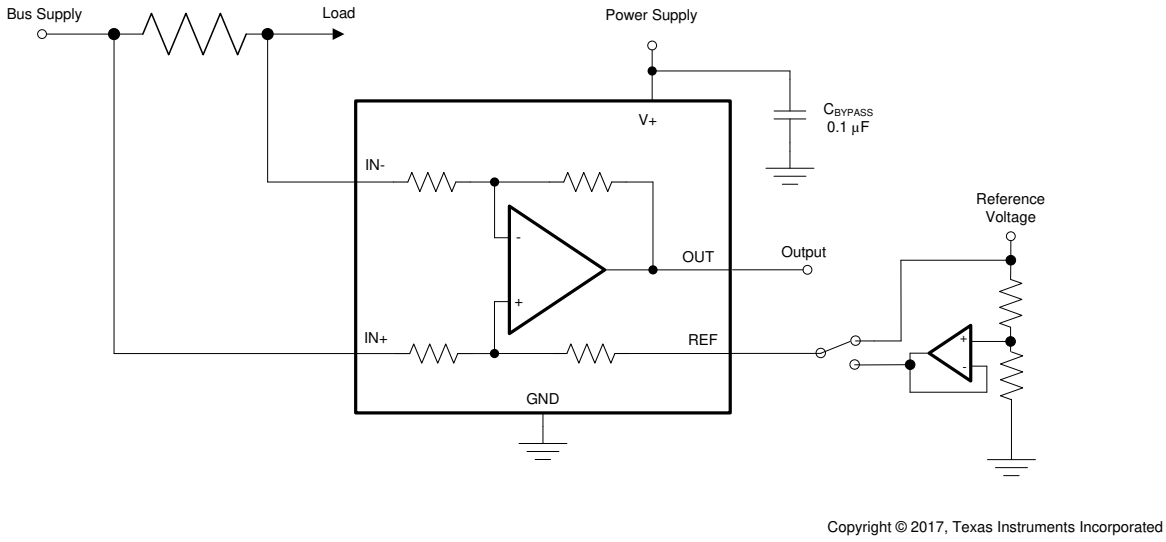


Figure 7-2. Unidirectional Application Output Response

7.2.2 Bidirectional Operation



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Figure 7-3. Bidirectional Application Schematic

7.2.2.1 Design Requirements

The device is a bidirectional, current-sense amplifier capable of measuring currents through a resistive shunt in two directions. This bidirectional monitoring is common in applications that include charging and discharging operations where the current flow-through resistor can change directions.

7.2.2.2 Detailed Design Procedure

The ability to measure this current flowing in both directions is enabled by applying a voltage to the REF pin, as shown in Figure 7-3. The voltage applied to REF (V_{REF}) sets the output state that corresponds to the zero-input level state. The output then responds by increasing above V_{REF} for positive differential signals (relative to the IN– pin) and responds by decreasing below V_{REF} for negative differential signals. This reference voltage applied to the REF pin can be set anywhere between 0 V to V+. For bidirectional applications, V_{REF} is typically set at midscale for equal signal range in both current directions. In some cases, however, V_{REF} is set at a voltage other than midscale when the bidirectional current and corresponding output signal do not need to be symmetrical.

7.2.2.3 Application Curve

An example output response of a bidirectional configuration is shown in Figure 7-4. With the REF pin connected to a reference voltage (2.5 V in this case) the output voltage is biased upwards by this reference level. The output rises above the reference voltage for positive differential input signals and falls below the reference voltage for negative differential input signals.

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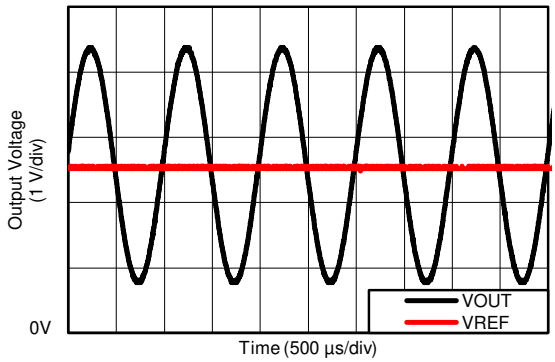


Figure 7-4. Bidirectional Application Output Response

8 Power Supply Recommendations

The input circuitry of the INA21x can accurately measure beyond the power-supply voltage, V+. For example, the V+ power supply can be 5 V, whereas the load power-supply voltage can be as high as 26 V. However, the output voltage range of the OUT pin is limited by the voltages on the power-supply pin. Note also that the INA21x can withstand the full input signal range up to 26 V at the input pins, regardless of whether the device has power applied or not.

9 Layout

9.1 Layout Guidelines

- Connect the input pins to the sensing resistor using a Kelvin or 4-wire connection. This connection technique ensures that only the current-sensing resistor impedance is detected between the input pins. Poor routing of the current-sensing resistor commonly results in additional resistance present between the input pins. Given the very low ohmic value of the current resistor, any additional high-current carrying impedance can cause significant measurement errors.
- Place the power-supply bypass capacitor as closely as possible to the supply and ground pins. The recommended value of this bypass capacitor is 0.1 µF. Additional decoupling capacitance can be added to compensate for noisy or high-impedance power supplies.

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9.2 Layout Example

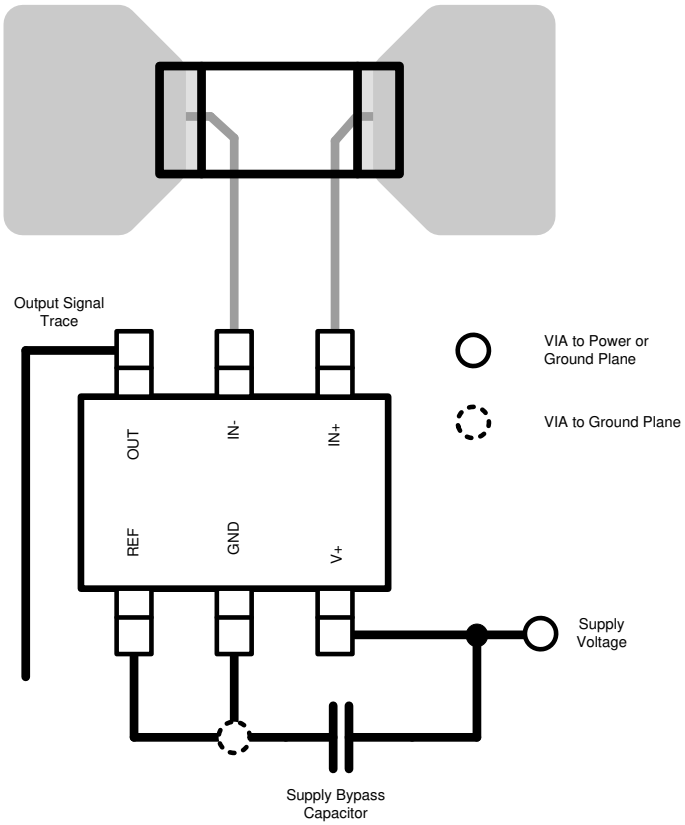


Figure 9-1. Recommended Layout

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10 Device and Documentation Support

10.1 Documentation Support

10.1.1 Related Documentation

For related documentation see the following:

- *INA210-215EVM User's Guide*

10.2 Related Links

Table 10-1 lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 10-1. Related Links

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
INA210	Click here	Click here	Click here	Click here	Click here
INA211	Click here	Click here	Click here	Click here	Click here
INA212	Click here	Click here	Click here	Click here	Click here
INA213	Click here	Click here	Click here	Click here	Click here
INA214	Click here	Click here	Click here	Click here	Click here
INA215	Click here	Click here	Click here	Click here	Click here

10.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.4 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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All trademarks are the property of their respective owners.

10.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.7 Glossary

TI Glossary — This glossary lists and explains terms, acronyms, and definitions.

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11 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision J (February 2017) to Revision K (October 2023) **Page**

- Updated format to match new TI layout and flow. Tables, figures and cross-references use a new numbering sequence throughout the document ... 1

Changes from Revision I (September 2016) to Revision J (February 2017) **Page**

- Added 2017 copyright to front page graphic ... 1
- Deleted *Device Options* table ... 3
- Added Common-mode analog inputs (Versions B and C) to *Absolute Maximum Ratings* table ... 4
- Changed HBM ESD value (Version A) from 4000 to 2000 V in *ESD Ratings* table ... 4
- Changed formatting of *Thermal Information* table note ... 5
- Deleted static literature number from document reference in *Related Documentation* section ... 25

Changes from Revision H (June 2016) to Revision I (September 2016) **Page**

- Deleted all notes regarding preview devices throughout data sheet; all devices now active ... 1

Changes from Revision G (July 2014) to Revision H (June 2016) **Page**

- Changed Features section: deleted last bullet, changed packages bullet ... 1
- Deleted last *Applications* bullet ... 1
- Changed *Description* section ... 1
- Changed *Device Information* table ... 1
- Moved storage temperature to *Absolute Maximum Ratings* table ... 4
- Changed *ESD Ratings* table: changed title, changed format to current standards ... 4
- Deleted both *Machine Model* rows from *ESD Ratings* table ... 4
- Changed first sentence referencing Equation 1 in *Input Filtering* section: replaced *seen* with *measured* ... 14
- Changed second sentence referencing Equation 1 in *Input Filtering* section ... 14
- Corrected punctuation and added clarity to first and second paragraphs in *Shutting Down the INA21x Series* section ... 16
- Changed *impressed* to *present* in fourth paragraph of *Shutting Down the INA21x Series* section ... 16

Changes from Revision F (June 2014) to Revision G (July 2014) **Page**

- Changed Simplified Schematic: added equation below gain table ... 1
- Changed $V_{(ESD)}$ *HBM* specifications for version A in Handling Ratings table ... 4

Changes from Revision E (June 2013) to Revision F (June 2014) **Page**

- Changed format to meet latest data sheet standards; added Pin Functions, Recommended Operating Conditions, and Thermal Information tables, *Overview*, *Functional Block Diagram*, *Application Information*, *Power Supply Recommendations*, and *Layout* sections, and moved existing sections ... 1
- Added INA215 to document ... 1
- Added INA215 sub-bullet to fourth Features bullet ... 1
- Added INA215 to simplified schematic table ... 1
- Added Thermal Information table ... 4
- Added INA215 to Figure 5-7 ... 8
- Added INA215 to Figure 5-15 ... 8
- Added INA215 to Figure 6-3 ... 16

Changes from Revision D (November 2012) to Revision E (June 2013) **Page**

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Changes from Revision C (August 2012) to Revision D (November 2012) **Page**

- Changed Frequency Response, *Bandwidth* parameter in Electrical Characteristics table....4

Changes from Revision B (June 2009) to Revision C (August 2012) **Page**

- Added silicon version B row to Input, *Common-Mode Input Range* parameter in Electrical Characteristics table....4
- Added silicon version B ESD ratings to Abs Max table....4
- Corrected typo in Figure 5-9 8
- Updated Figure 5-12 8
- Changed *Input Filtering* section....14
- Added *Improving Transient Robustness* section....19

Changes from Revision A (June 2008) to Revision B () **Page**

- Added RSW package to device photo....1
- Added UQFN package to *Features* list....1
- Updated front page graphic....1
- Added RSW package pin out drawing....3
- Added footnote 3 to *Electrical Characteristics* table....4
- Added UQFN package information to *Temperature Range* section of *Electrical Characteristics* table....4
- Changed Figure 5-2 to reflect operating temperature range....8
- Changed Figure 5-4 to reflect operating temperature range....8
- Changed Figure 5-6 to reflect operating temperature range....8
- Changed Figure 5-13 to reflect operating temperature range....8
- Changed Figure 5-14 to reflect operating temperature range....8
- Added RSW description to the *Basic Connections* section....13
- Changed 60 µV to 100 µV in last sentence of the *Selecting RS* section....13

Changes from Revision * (May 2008) to Revision A () **Page**

- Deleted first footnote of *Electrical Characteristics* table....4
- Changed Figure 5-7 8
- Changed Figure 5-15 8

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12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA210AIDCKJ	Active	Production	SC70 (DCK) | 6	10000 | JUMBO T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CET
INA210AIDCKJ.B	Active	Production	SC70 (DCK) | 6	10000 | JUMBO T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CET
INA210AIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	CET
INA210AIDCKR.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CET
INA210AIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CET
INA210AIDCKR1G4.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
INA210AIDCKR1G4.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
INA210AIDCKT	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	CET
INA210AIDCKT.A	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CET
INA210AIDCKT.B	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CET
INA210AIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KNJ
INA210AIRSWR.A	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KNJ
INA210AIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KNJ
INA210AIRSWRG4	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KNJ
INA210AIRSWRG4.A	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KNJ
INA210AIRSWRG4.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KNJ
INA210AIRSWT	Obsolete	Production	UQFN (RSW) | 10	-	-	Call TI	Call TI	-40 to 125	(KNJ, NSJ)
INA210BIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	SED
INA210BIDCKR.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SED
INA210BIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SED
INA210BIDCKRG4.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
INA210BIDCKRG4.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
INA210BIDCKT	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	SED
INA210BIDCKT.A	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SED
INA210BIDCKT.B	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SED
INA210BIDCKTG4	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SED
INA210BIDCKTG4.A	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SED
INA210BIDCKTG4.B	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SED
INA210BIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHQ

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA210BIRSWR.A	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHQ
INA210BIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHQ
INA210CIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	16B
INA210CIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	16B
INA210CIDCKRG4	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	16B
INA210CIDCKRG4.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	16B
INA210CIDCKT	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	16B
INA210CIDCKT.B	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	16B
INA210CIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16C
INA210CIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16C
INA211AIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	CEU
INA211AIDCKR.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CEU
INA211AIDCKT	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	CEU
INA211AIDCKT.A	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CEU
INA211BIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	SEE
INA211BIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEE
INA211BIDCKT	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	SEE
INA211BIDCKT.B	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEE
INA211BIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	13Q
INA211BIRSWR.A	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	13Q
INA211BIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	13Q
INA211BIRSWT	Obsolete	Production	UQFN (RSW) | 10	-	-	Call TI	Call TI	-40 to 125	13Q
INA211CIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	16D
INA211CIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	16D
INA211CIDCKT	Obsolete	Production	SC70 (DCK) | 6	-	-	Call TI	Call TI	-40 to 125	16D
INA211CIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16U
INA211CIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16U
INA211CIRSWRG4	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16U
INA211CIRSWRG4.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16U
INA211CIRSWT	Obsolete	Production	UQFN (RSW) | 10	-	-	Call TI	Call TI	-40 to 125	16U
INA212AIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	CEV

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA212AIDCKR.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CEV
INA212AIDCKT	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	CEV
INA212AIDCKT.A	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CEV
INA212BIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	SEC
INA212BIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEC
INA212BIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	13U
INA212BIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	13U
INA212CIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	16E
INA212CIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	16E
INA212CIDCKT	Obsolete	Production	SC70 (DCK) | 6	-	-	Call TI	Call TI	-40 to 125	16E
INA212CIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16V
INA212CIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16V
INA212CIRSWT	Obsolete	Production	UQFN (RSW) | 10	-	-	Call TI	Call TI	-40 to 125	16V
INA213AIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	CFT
INA213AIDCKR.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CFT
INA213AIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CFT
INA213AIDCKRG4	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CFT
INA213AIDCKRG4.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CFT
INA213AIDCKRG4.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CFT
INA213AIDCKT	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	CFT
INA213AIDCKT.A	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CFT
INA213AIDCKT.B	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CFT
INA213AIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KPJ
INA213AIRSWR.A	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KPJ
INA213AIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KPJ
INA213AIRSWRG4	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KPJ
INA213AIRSWRG4.A	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KPJ
INA213AIRSWRG4.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KPJ
INA213AIRSWT	Obsolete	Production	UQFN (RSW) | 10	-	-	Call TI	Call TI	-40 to 125	KPJ
INA213BIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	SEF
INA213BIDCKR.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEF

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA213BIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEF
INA213BIDCKRG4.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
INA213BIDCKRG4.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
INA213BIDCKT	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	SEF
INA213BIDCKT.A	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEF
INA213BIDCKT.B	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEF
INA213BIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHT
INA213BIRSWR.A	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHT
INA213BIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHT
INA213BIRSWT	Obsolete	Production	UQFN (RSW) | 10	-	-	Call TI	Call TI	-40 to 125	SHT
INA213CIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	16F
INA213CIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	16F
INA213CIDCKT	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	16F
INA213CIDCKT.B	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	16F
INA213CIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16W
INA213CIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16W
INA213CIRSWT	Obsolete	Production	UQFN (RSW) | 10	-	-	Call TI	Call TI	-40 to 125	16W
INA214AIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	CFV
INA214AIDCKR.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CFV
INA214AIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CFV
INA214AIDCKRG4	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CFV
INA214AIDCKRG4.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CFV
INA214AIDCKRG4.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CFV
INA214AIDCKT	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	CFV
INA214AIDCKT.A	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CFV
INA214AIDCKT.B	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	CFV
INA214AIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KRJ
INA214AIRSWR.A	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KRJ
INA214AIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KRJ
INA214AIRSWRG4	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KRJ
INA214AIRSWRG4.A	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KRJ

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA214AIRSWRG4.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	KRJ
INA214AIRSWT	Obsolete	Production	UQFN (RSW) | 10	-	-	Call TI	Call TI	-40 to 125	KRJ
INA214BIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	SEA
INA214BIDCKR.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEA
INA214BIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEA
INA214BIDCKRG4.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
INA214BIDCKRG4.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
INA214BIDCKT	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	SEA
INA214BIDCKT.A	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEA
INA214BIDCKT.B	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SEA
INA214BIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHU
INA214BIRSWR.A	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHU
INA214BIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SHU
INA214CIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	16G
INA214CIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	16G
INA214CIDCKRG4	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	16G
INA214CIDCKRG4.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	16G
INA214CIDCKT	Obsolete	Production	SC70 (DCK) | 6	-	-	Call TI	Call TI	-40 to 125	16G
INA214CIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16X
INA214CIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16X
INA214CIRSWRG4	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16X
INA214CIRSWRG4.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16X
INA214CIRSWT	Obsolete	Production	UQFN (RSW) | 10	-	-	Call TI	Call TI	-40 to 125	16X
INA215AIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	SME
INA215AIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SME
INA215AIDCKRG4.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
INA215AIDCKT	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	SME
INA215AIDCKT.B	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	SME
INA215BIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	13S
INA215BIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	13S
INA215BIDCKT	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	13S

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA215BIDCKT.B	Active	Production	SC70 (DCK) | 6	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	13S
INA215BIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	13R
INA215BIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	13R
INA215CIDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-2-260C-1 YEAR	-40 to 125	17K
INA215CIDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	17K
INA215CIDCKT	Obsolete	Production	SC70 (DCK) | 6	-	-	Call TI	Call TI	-40 to 125	17K
INA215CIRSWR	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16Z
INA215CIRSWR.B	Active	Production	UQFN (RSW) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	16Z

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF INA210, INA211, INA212, INA213, INA214, INA215 :

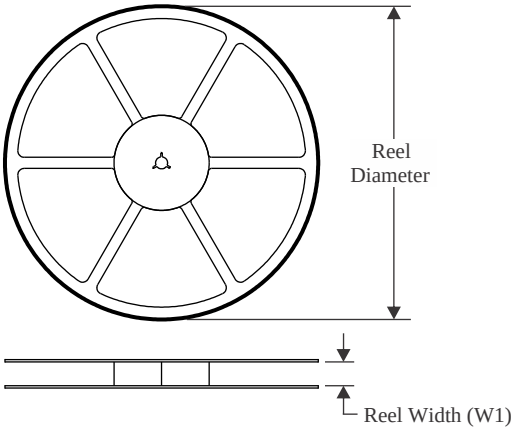
- Automotive : INA210-Q1, INA211-Q1, INA212-Q1, INA213-Q1, INA214-Q1, INA215-Q1

NOTE: Qualified Version Definitions:

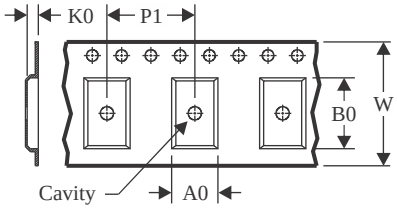
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

REEL DIMENSIONS

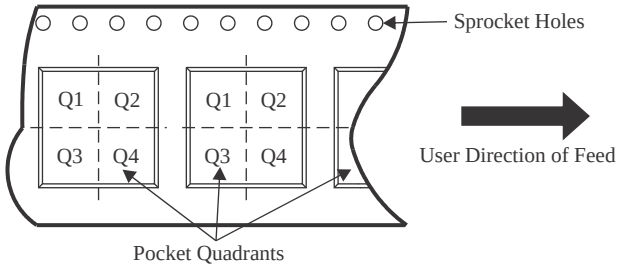


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

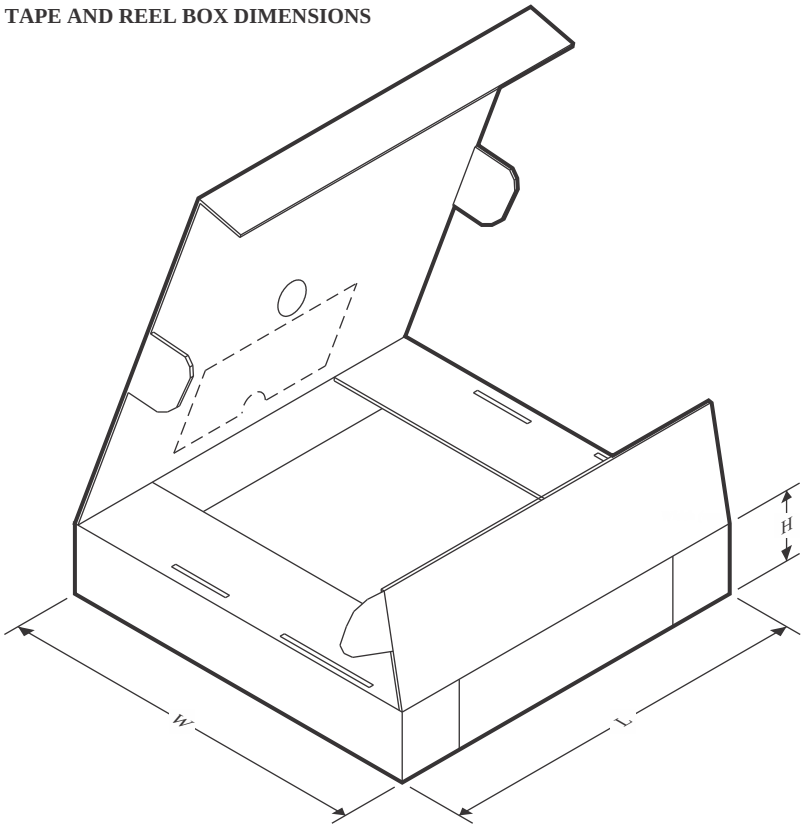
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA210AIDCKJ	SC70	DCK	6	10000	330.0	8.4	2.4	2.5	1.2	4.0	8.0	Q3
INA210AIDCKR	SC70	DCK	6	3000	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
INA210AIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA210AIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA210AIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA210AIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA210AIDCKT	SC70	DCK	6	250	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
INA210AIRSWR	UQFN	RSW	10	3000	179.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA210AIRSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA210AIRSWRG4	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA210BIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA210BIDCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA210BIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA210BIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA210BIDCKT	SC70	DCK	6	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA210BIDCKTG4	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA210BIRSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA210CIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA210CIDCKRG4	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA210CIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA210CIRSWR	UQFN	RSW	10	3000	180.0	9.5	1.6	2.0	0.8	4.0	8.0	Q1
INA211AIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA211AIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA211AIDCKT	SC70	DCK	6	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
INA211AIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA211AIDCKT	SC70	DCK	6	250	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
INA211BIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA211BIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA211BIDCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA211BIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA211BIDCKT	SC70	DCK	6	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA211BIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA211BIRSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA211BIRSWR	UQFN	RSW	10	3000	179.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA211CIDCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA211CIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA211CIRSWR	UQFN	RSW	10	3000	180.0	9.5	1.6	2.0	0.8	4.0	8.0	Q1
INA211CIRSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA211CIRSWRG4	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA212AIDCKR	SC70	DCK	6	3000	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
INA212AIDCKR	SC70	DCK	6	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
INA212AIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA212AIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA212AIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA212AIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA212AIDCKT	SC70	DCK	6	250	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
INA212AIDCKT	SC70	DCK	6	250	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
INA212BIDCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA212BIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA212BIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA212BIRSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA212CIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA212CIDCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA212CIRSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA213AIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA213AIDCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA213AIDCKR	SC70	DCK	6	3000	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA213AIDCKRG4	SC70	DCK	6	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
INA213AIDCKRG4	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA213AIDCKRG4	SC70	DCK	6	3000	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
INA213AIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA213AIDCKT	SC70	DCK	6	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA213AIDCKT	SC70	DCK	6	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
INA213AIDCKT	SC70	DCK	6	250	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
INA213AIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA213AIRSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA213AIRSWRG4	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA213BIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA213BIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA213BIDCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA213BIDCKT	SC70	DCK	6	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA213BIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA213BIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA213BIRSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA213CIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA213CIDCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA213CIDCKT	SC70	DCK	6	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA213CIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA213CIRSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA213CIRSWR	UQFN	RSW	10	3000	180.0	9.5	1.6	2.0	0.8	4.0	8.0	Q1
INA213CIRSWR	UQFN	RSW	10	3000	179.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA214AIDCKR	SC70	DCK	6	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
INA214AIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA214AIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA214AIDCKR	SC70	DCK	6	3000	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
INA214AIDCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA214AIDCKRG4	SC70	DCK	6	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
INA214AIDCKRG4	SC70	DCK	6	3000	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
INA214AIDCKRG4	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA214AIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA214AIDCKT	SC70	DCK	6	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA214AIRSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA214AIRSWRG4	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA214BIDCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA214BIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA214BIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA214BIDCKT	SC70	DCK	6	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA214BIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA214BIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA214BIRSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA214CIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA214CIDCKRG4	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA214CIRSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA214CIRSWRG4	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA215AIDCKR	SC70	DCK	6	3000	178.0	8.4	2.4	2.5	1.2	4.0	8.0	Q3
INA215AIDCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA215AIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA215AIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA215AIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA215AIDCKT	SC70	DCK	6	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA215BIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA215BIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA215BIDCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA215BIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA215BIDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA215BIDCKT	SC70	DCK	6	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA215BIRSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA215CIDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA215CIDCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
INA215CIRSWR	UQFN	RSW	10	3000	180.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA210AIDCKJ	SC70	DCK	6	10000	366.0	364.0	50.0
INA210AIDCKR	SC70	DCK	6	3000	202.0	201.0	28.0
INA210AIDCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA210AIDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA210AIDCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA210AIDCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA210AIDCKT	SC70	DCK	6	250	213.0	191.0	35.0
INA210AIRSWR	UQFN	RSW	10	3000	200.0	183.0	25.0
INA210AIRSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA210AIRSWRG4	UQFN	RSW	10	3000	210.0	185.0	35.0
INA210BIDCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA210BIDCKR	SC70	DCK	6	3000	210.0	185.0	35.0
INA210BIDCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA210BIDCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA210BIDCKT	SC70	DCK	6	250	210.0	185.0	35.0
INA210BIDCKTG4	SC70	DCK	6	250	180.0	180.0	18.0
INA210BIRSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA210CIDCKR	SC70	DCK	6	3000	340.0	340.0	38.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA210CIDCKRG4	SC70	DCK	6	3000	340.0	340.0	38.0
INA210CIDCKT	SC70	DCK	6	250	340.0	340.0	38.0
INA210CIRSWR	UQFN	RSW	10	3000	189.0	185.0	36.0
INA211AIDCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA211AIDCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA211AIDCKT	SC70	DCK	6	250	223.0	270.0	35.0
INA211AIDCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA211AIDCKT	SC70	DCK	6	250	213.0	191.0	35.0
INA211BIDCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA211BIDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA211BIDCKR	SC70	DCK	6	3000	210.0	185.0	35.0
INA211BIDCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA211BIDCKT	SC70	DCK	6	250	210.0	185.0	35.0
INA211BIDCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA211BIRSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA211BIRSWR	UQFN	RSW	10	3000	200.0	183.0	25.0
INA211CIDCKR	SC70	DCK	6	3000	210.0	185.0	35.0
INA211CIDCKR	SC70	DCK	6	3000	340.0	340.0	38.0
INA211CIRSWR	UQFN	RSW	10	3000	189.0	185.0	36.0
INA211CIRSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA211CIRSWRG4	UQFN	RSW	10	3000	210.0	185.0	35.0
INA212AIDCKR	SC70	DCK	6	3000	223.0	270.0	35.0
INA212AIDCKR	SC70	DCK	6	3000	195.0	200.0	45.0
INA212AIDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA212AIDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA212AIDCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA212AIDCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA212AIDCKT	SC70	DCK	6	250	223.0	270.0	35.0
INA212AIDCKT	SC70	DCK	6	250	213.0	191.0	35.0
INA212BIDCKR	SC70	DCK	6	3000	210.0	185.0	35.0
INA212BIDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA212BIDCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA212BIRSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA212CIDCKR	SC70	DCK	6	3000	340.0	340.0	38.0
INA212CIDCKR	SC70	DCK	6	3000	210.0	185.0	35.0
INA212CIRSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA213AIDCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA213AIDCKR	SC70	DCK	6	3000	210.0	185.0	35.0
INA213AIDCKR	SC70	DCK	6	3000	202.0	201.0	28.0
INA213AIDCKRG4	SC70	DCK	6	3000	213.0	191.0	35.0
INA213AIDCKRG4	SC70	DCK	6	3000	180.0	180.0	18.0
INA213AIDCKRG4	SC70	DCK	6	3000	202.0	201.0	28.0
INA213AIDCKT	SC70	DCK	6	250	180.0	180.0	18.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA213AIDCKT	SC70	DCK	6	250	210.0	185.0	35.0
INA213AIDCKT	SC70	DCK	6	250	223.0	270.0	35.0
INA213AIDCKT	SC70	DCK	6	250	213.0	191.0	35.0
INA213AIDCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA213AIRSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA213AIRSWRG4	UQFN	RSW	10	3000	210.0	185.0	35.0
INA213BIDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA213BIDCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA213BIDCKR	SC70	DCK	6	3000	210.0	185.0	35.0
INA213BIDCKT	SC70	DCK	6	250	210.0	185.0	35.0
INA213BIDCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA213BIDCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA213BIRSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA213CIDCKR	SC70	DCK	6	3000	340.0	340.0	38.0
INA213CIDCKR	SC70	DCK	6	3000	210.0	185.0	35.0
INA213CIDCKT	SC70	DCK	6	250	210.0	185.0	35.0
INA213CIDCKT	SC70	DCK	6	250	340.0	340.0	38.0
INA213CIRSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA213CIRSWR	UQFN	RSW	10	3000	189.0	185.0	36.0
INA213CIRSWR	UQFN	RSW	10	3000	200.0	183.0	25.0
INA214AIDCKR	SC70	DCK	6	3000	213.0	191.0	35.0
INA214AIDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA214AIDCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA214AIDCKR	SC70	DCK	6	3000	202.0	201.0	28.0
INA214AIDCKR	SC70	DCK	6	3000	210.0	185.0	35.0
INA214AIDCKRG4	SC70	DCK	6	3000	213.0	191.0	35.0
INA214AIDCKRG4	SC70	DCK	6	3000	202.0	201.0	28.0
INA214AIDCKRG4	SC70	DCK	6	3000	180.0	180.0	18.0
INA214AIDCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA214AIDCKT	SC70	DCK	6	250	210.0	185.0	35.0
INA214AIRSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA214AIRSWRG4	UQFN	RSW	10	3000	210.0	185.0	35.0
INA214BIDCKR	SC70	DCK	6	3000	210.0	185.0	35.0
INA214BIDCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA214BIDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA214BIDCKT	SC70	DCK	6	250	210.0	185.0	35.0
INA214BIDCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA214BIDCKT	SC70	DCK	6	250	180.0	180.0	18.0
INA214BIRSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA214CIDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA214CIDCKRG4	SC70	DCK	6	3000	180.0	180.0	18.0
INA214CIRSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA214CIRSWRG4	UQFN	RSW	10	3000	210.0	185.0	35.0

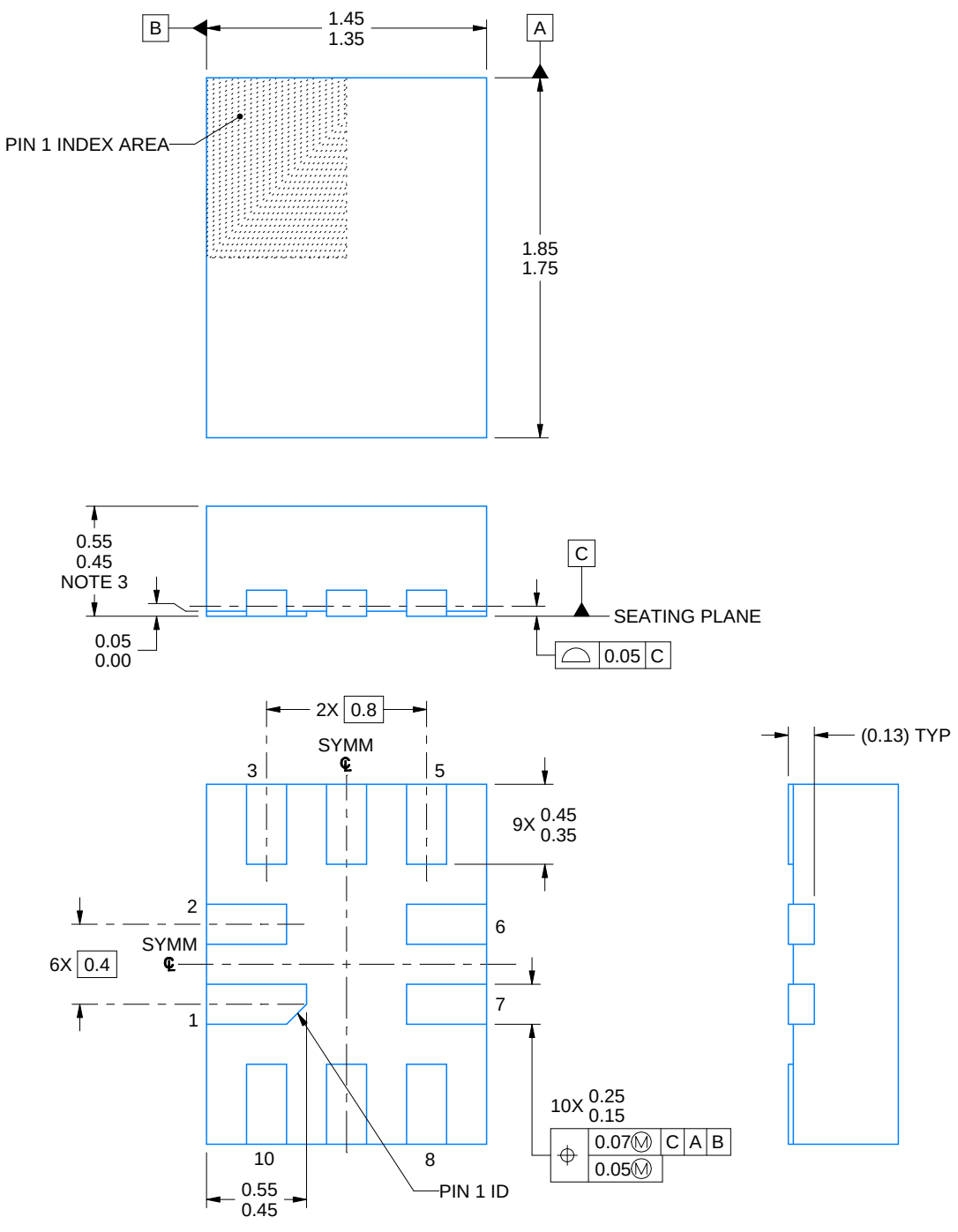
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA215AIDCKR	SC70	DCK	6	3000	340.0	340.0	38.0
INA215AIDCKR	SC70	DCK	6	3000	210.0	185.0	35.0
INA215AIDCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA215AIDCKT	SC70	DCK	6	250	340.0	340.0	38.0
INA215AIDCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA215AIDCKT	SC70	DCK	6	250	210.0	185.0	35.0
INA215BIDCKR	SC70	DCK	6	3000	340.0	340.0	38.0
INA215BIDCKR	SC70	DCK	6	3000	190.0	190.0	30.0
INA215BIDCKR	SC70	DCK	6	3000	210.0	185.0	35.0
INA215BIDCKT	SC70	DCK	6	250	340.0	340.0	38.0
INA215BIDCKT	SC70	DCK	6	250	190.0	190.0	30.0
INA215BIDCKT	SC70	DCK	6	250	210.0	185.0	35.0
INA215BIRSWR	UQFN	RSW	10	3000	210.0	185.0	35.0
INA215CIDCKR	SC70	DCK	6	3000	340.0	340.0	38.0
INA215CIDCKR	SC70	DCK	6	3000	210.0	185.0	35.0
INA215CIRSWR	UQFN	RSW	10	3000	210.0	185.0	35.0

PACKAGE OUTLINE

RSW0010A

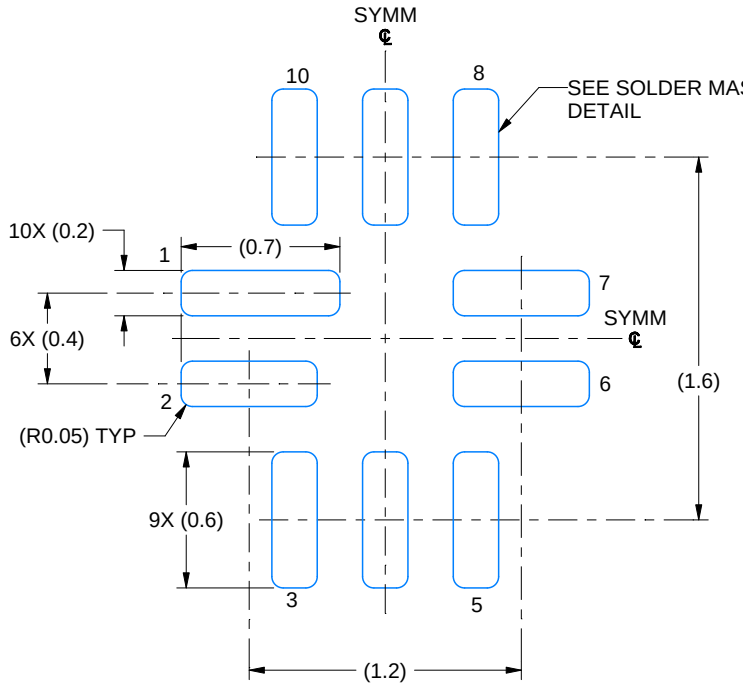
UQFN - 0.55 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

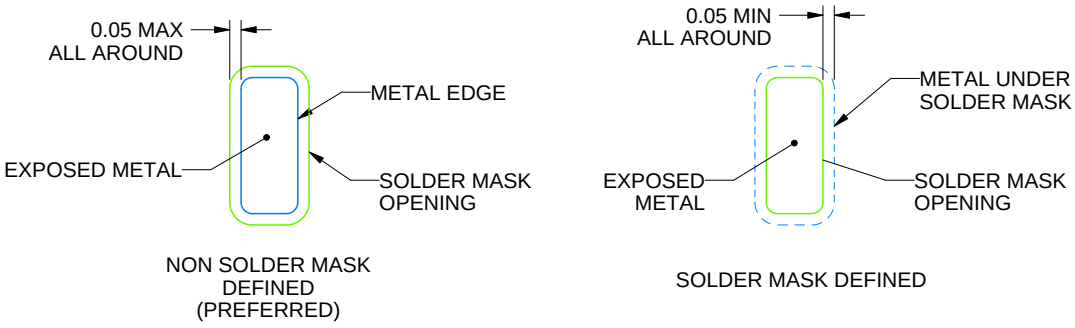


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package complies to JEDEC MO-288 variation UDEE, except minimum package height.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 30X

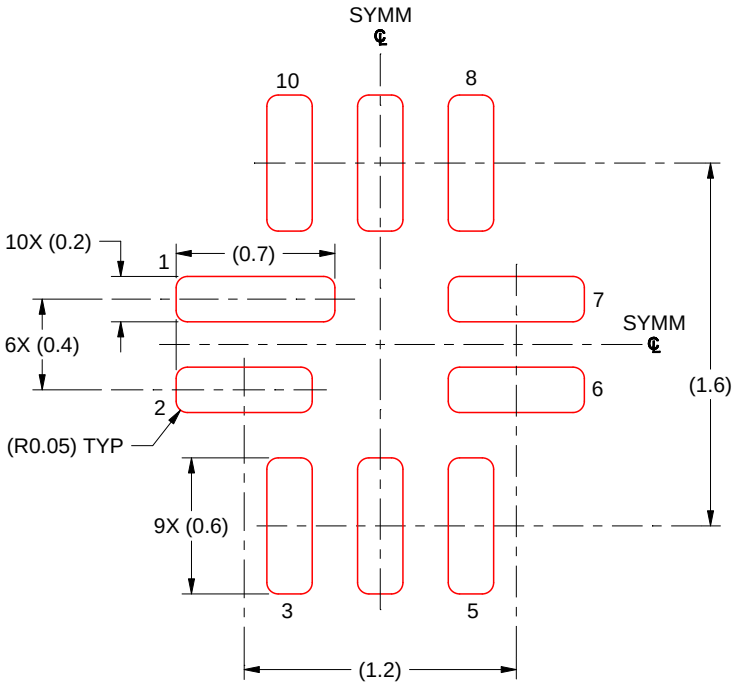


SOLDER MASK DETAILS

4224897/A 03/2019

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 30X

4224897/A 03/2019

NOTES: (continued)

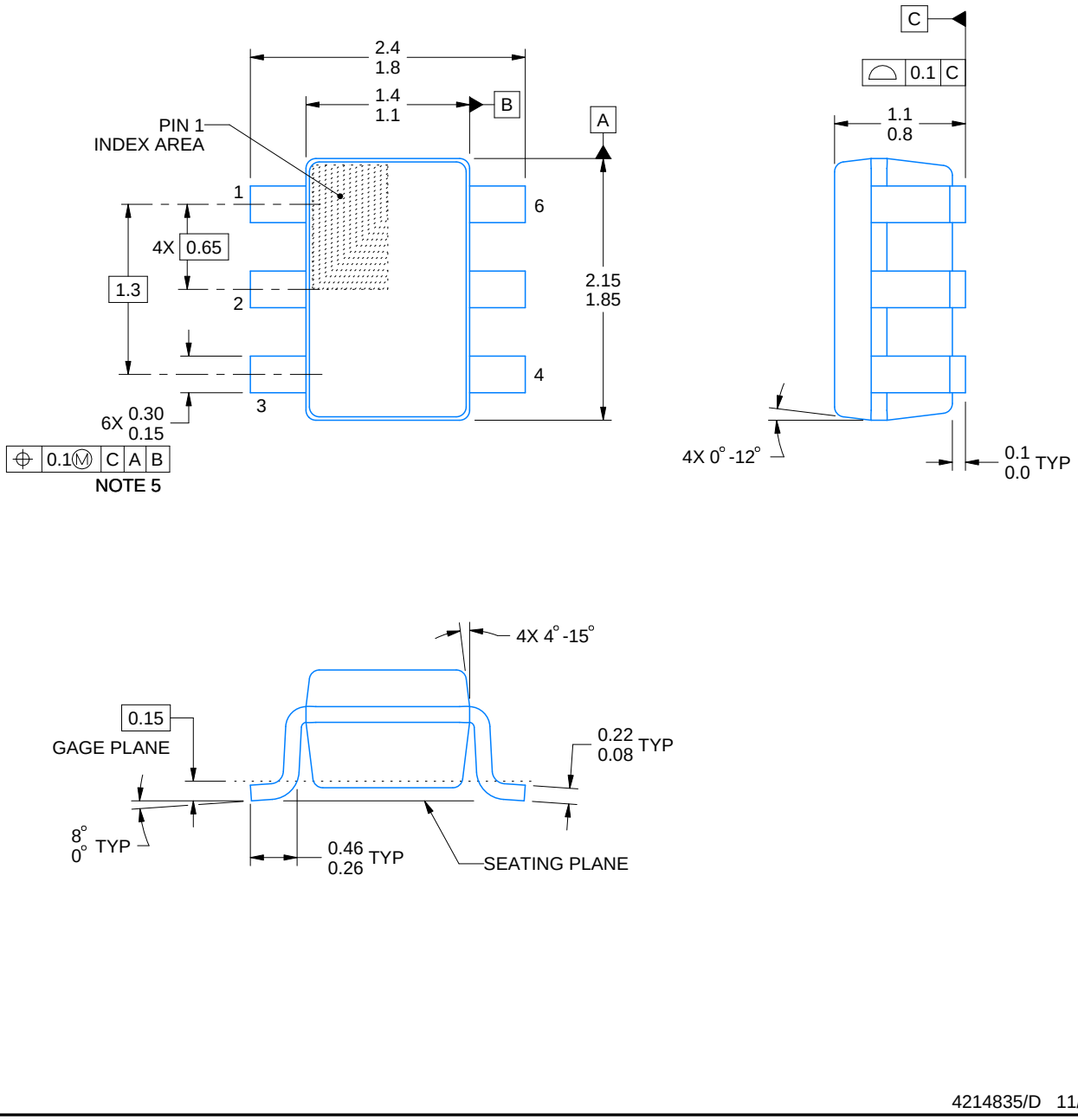
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

PACKAGE OUTLINE

DCK0006A

SOT - 1.1 max height

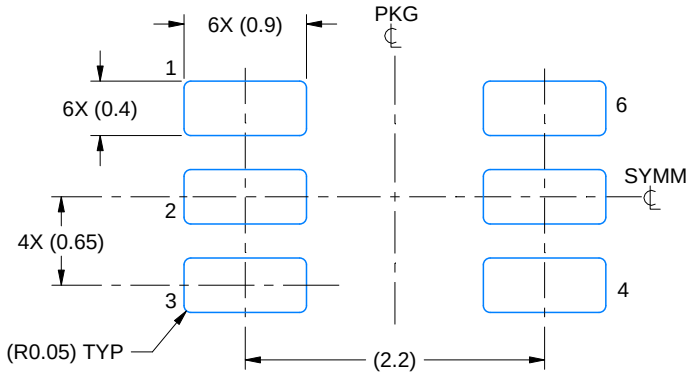
SMALL OUTLINE TRANSISTOR



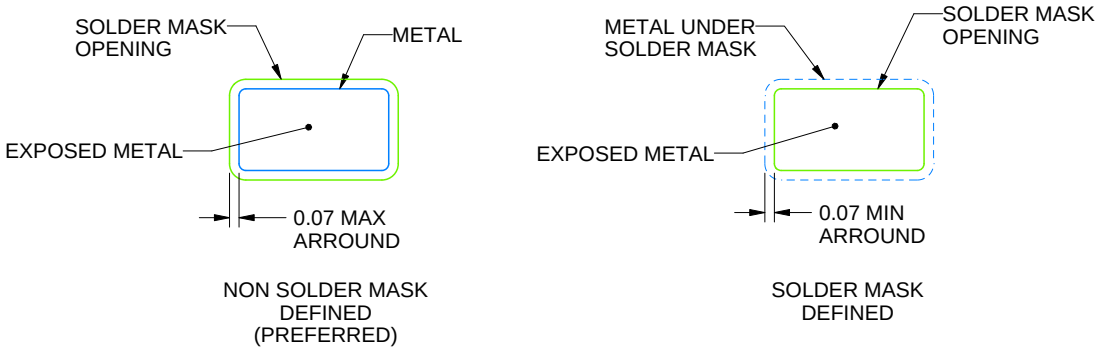
4214835/D 11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
4. Falls within JEDEC MO-203 variation AB.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X

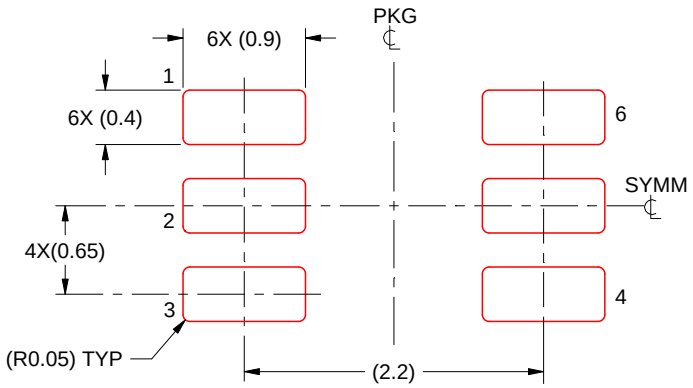


SOLDER MASK DETAILS

4214835/D 11/2024

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214835/D 11/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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Last updated 10/2025